

# MUX36xxx 36V 低电容、低泄漏电流、高精度模拟多路复用器

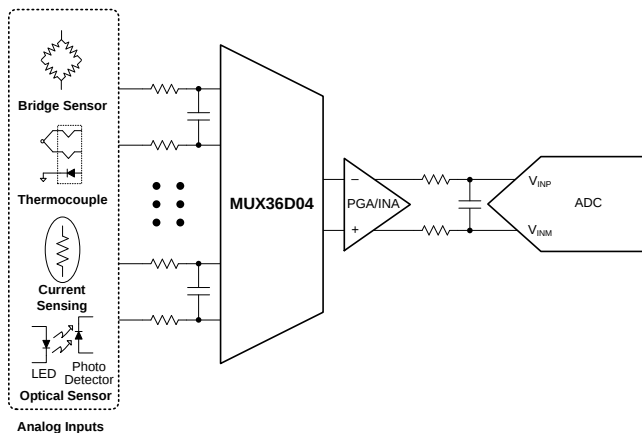
## 1 特性

- 低导通电阻
  - MUX36S08: 9.4pF
  - MUX36D04: 6.7pF
- 低泄漏电流: 1pA
- 低电荷注入: 0.3pC
- 轨至轨运行
- 宽电源电压范围:  $\pm 5V$  至  $\pm 18V$  或  $10V$  至  $36V$
- 低导通电阻:  $125\Omega$
- 转换时间: 92ns
- 先断后合开关操作
- EN 引脚与  $V_{DD}$  相连
- 逻辑电平:  $2V$  至  $V_{DD}$
- 低电源电流:  $45\mu A$
- ESD 保护 HBM: 2000V
- 行业标准 TSSOP 封装和更小型的 WQFN 封装
- 有关其他配置, 请参阅:
  - TMUX6111/ 12/ 13 (4 通道 SPST)
  - TMUX6121/ 22/ 23 (2 通道 SPST)
  - TMUX6119 (1 通道 SPDT)
  - TMUX6136 (2 通道 SPDT)
  - TMUX6104 (1 通道 4:1)

## 2 应用

- 工厂自动化和工业过程控制
- 可编程逻辑控制器 (PLC)
- 模拟输入模块
- 自动测试设备
- 电池监控系统

简化电路原理图



## 3 说明

MUX36S08 和 MUX36D04 (MUX36xxx) 是现代互补金属氧化物半导体 (CMOS) 模拟多路复用器 (mux)。MUX36S08 提供 8:1 单端通道, 而 MUX36D04 提供差动 4:1 或双 4:1 单端通道。MUX36S08 和 MUX36D04 在双电源 ( $\pm 5V$  至  $\pm 18V$ ) 或单电源 ( $10V$  至  $36V$ ) 供电时均能正常运行。它们在由对称电源 (如  $V_{DD} = 12V$ 、 $V_{SS} = -12V$ ) 和非对称电源 (如  $V_{DD} = 12V$ 、 $V_{SS} = -5V$ ) 供电时也能保证优异性能。所有数字输入具有兼容晶体管-晶体管逻辑电路 (TTL) 的阈值。当器件在有效电源电压范围内运行时, 该阈值可确保 TTL 和 CMOS 逻辑电路的兼容性。

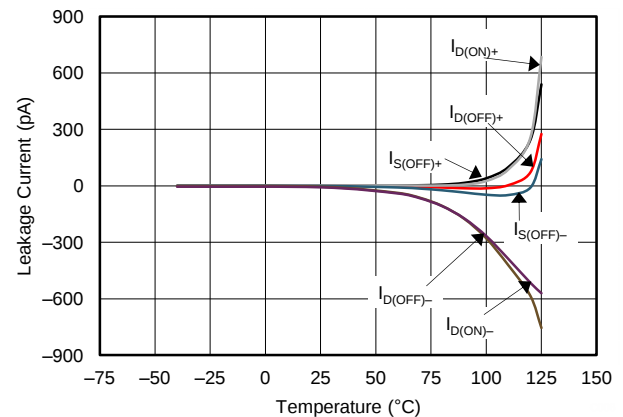
MUX36S08 和 MUX36D04 的导通和关断泄漏电流较低, 允许此类多路复用器以最小误差转换来源于高输入阻抗源的信号。仅为  $45\mu A$  的低电源电流支持其应用于便携式应用。

器件信息<sup>(1)</sup>

| 器件型号     | 封装         | 封装尺寸 (标称值)      |
|----------|------------|-----------------|
| MUX36S08 | TSSOP (16) | 5.00mm × 4.40mm |
| MUX36D04 | WQFN (16)  | 4.00mm × 4.00mm |

(1) 如需了解所有可用封装, 请参阅数据表末尾的封装选项附录。

泄漏电流与温度间的关系



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## 4 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

| Changes from Revision C (April 2018) to Revision D                                | Page |
|-----------------------------------------------------------------------------------|------|
| • 已添加 特征：有关其他配置，请参阅                                                               | 1    |
| • Added RRJ (WQFN) package option to the MUX36D08                                 | 4    |
| • Changed the WQFN S6 pin number From: 19 To: 9                                   | 4    |
| • Added the RRJ package option to the MUX36D04                                    | 5    |
| • Added WQFN (RRJ) data to <i>Thermal Information</i>                             | 7    |
| • Changed On-resistance drift unit value From: $\Omega$ To: $\%/^{\circ}\text{C}$ | 7    |
| • Changed $I_{DL(ON)}$ unit value From: nA To: pA                                 | 7    |

| Changes from Revision B (July 2016) to Revision C                                                                                                                                                                     | Page |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|
| • 已添加 已将 WQFN 封装选项添加到 特性                                                                                                                                                                                              | 1    |
| • 已添加 已在器件信息中添加了 WQFN 封装选项                                                                                                                                                                                            | 1    |
| • Changed Description column of MUX36D04 row in <i>Device Comparison Table</i>                                                                                                                                        | 4    |
| • Added WQFN (RUM) data to <i>Thermal Information</i>                                                                                                                                                                 | 7    |
| • Changed On-resistance drift TYP value From: 0.52 To: 0.64 in <i>Electrical Characteristics: Dual Supply</i>                                                                                                         | 7    |
| • Changed Analog Switch, $I_D$ parameter in <i>Electrical Characteristics: Dual Supply</i> table: split parameter into $I_{D(OFF)}$ and $I_{D(ON)}$ parameters, changed symbols, parameter names, and test conditions | 7    |
| • Changed Analog Switch, $I_{DL(ON)}$ parameter test conditions in <i>Electrical Characteristics: Dual Supply</i> table                                                                                               | 7    |
| • Changed On-resistance drift TYP value From: 0.47 To: 1.13 in <i>Electrical Characteristics: Single Supply</i>                                                                                                       | 9    |
| • Changed Analog Switch, $I_D$ parameter in <i>Electrical Characteristics: Single Supply</i> table: split parameter into $I_{D(OFF)}$                                                                                 |      |

|                                                                                                     |    |
|-----------------------------------------------------------------------------------------------------|----|
| and $I_{D(ON)}$ parameters, changed symbols, parameter names, and $I_{D(ON)}$ test conditions ..... | 9  |
| • Changed and swapped data between 25°C and 85°C to fix the typo .....                              | 10 |
| • Changed 图 30: changed low-voltage level to 0 V .....                                              | 18 |
| • Changed 图 33: added 0 V line, flipped $V_S$ supply symbol .....                                   | 20 |
| • Changed 图 37: changed 5 $V_{RMS}$ marking in <i>Audio Precision</i> box.....                      | 22 |
| • Changed description of MUX36D04 in <i>Overview</i> section.....                                   | 23 |
| • Changed 图 43: changed OPA140 amplifier and charge kickback filter box .....                       | 27 |

**Changes from Revision A (January 2016) to Revision B**
**Page**

|                                                                                                    |    |
|----------------------------------------------------------------------------------------------------|----|
| • Added differential on-leakage current parameter to <i>Electrical Characteristics</i> table ..... | 7  |
| • Added <i>Differential On-Leakage Current</i> section.....                                        | 17 |

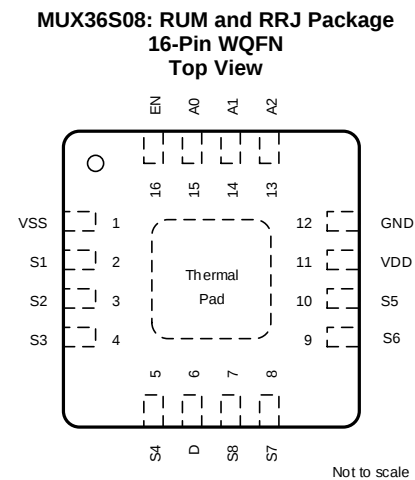
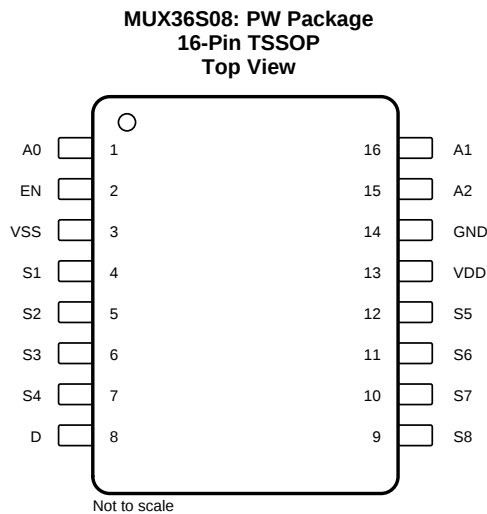
**Changes from Original (January 2016) to Revision A**
**Page**

|                           |   |
|---------------------------|---|
| • 已由“产品预览”更改为“量产数据” ..... | 1 |
|---------------------------|---|

## 5 Device Comparison Table

| PRODUCT  | DESCRIPTION                                                                  |
|----------|------------------------------------------------------------------------------|
| MUX36S08 | 8-channel, single-ended analog multiplexer (8:1 mux)                         |
| MUX36D04 | 4-channel differential or dual 4:1 single-ended analog multiplexer (8:2 mux) |

## 6 Pin Configuration and Functions



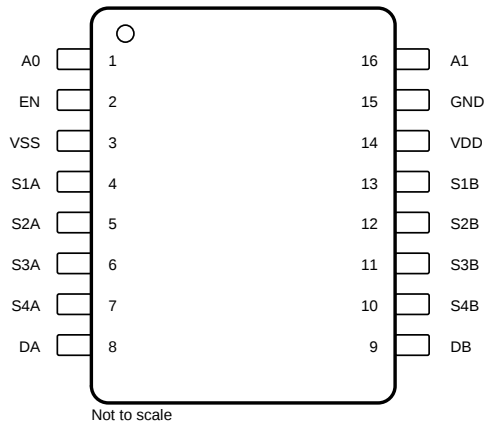
RUM and RRJ have the same package dimension, but different thermal pad dimension and lead finger length.

### Pin Functions: MUX36S08

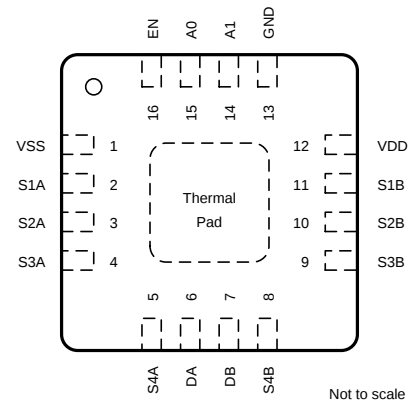
| NAME                       | PIN   |      | FUNCTION               | DESCRIPTION                                                                                                                                                                                                                                                              |
|----------------------------|-------|------|------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|                            | TSSOP | WQFN |                        |                                                                                                                                                                                                                                                                          |
| A0                         | 1     | 15   | Digital input          | Address line 0                                                                                                                                                                                                                                                           |
| A1                         | 16    | 14   | Digital input          | Address line 1                                                                                                                                                                                                                                                           |
| A2                         | 15    | 13   | Digital input          | Address line 2                                                                                                                                                                                                                                                           |
| D                          | 8     | 6    | Analog input or output | Drain pin. Can be an input or output.                                                                                                                                                                                                                                    |
| EN                         | 2     | 16   | Digital input          | Active high digital input. When this pin is low, all switches are turned off. When this pin is high, the A[2:0] logic inputs determine which switch is turned on.                                                                                                        |
| GND                        | 14    | 12   | Power supply           | Ground (0 V) reference                                                                                                                                                                                                                                                   |
| S1                         | 4     | 2    | Analog input or output | Source pin 1. Can be an input or output.                                                                                                                                                                                                                                 |
| S2                         | 5     | 3    | Analog input or output | Source pin 2. Can be an input or output.                                                                                                                                                                                                                                 |
| S3                         | 6     | 4    | Analog input or output | Source pin 3. Can be an input or output.                                                                                                                                                                                                                                 |
| S4                         | 7     | 5    | Analog input or output | Source pin 4. Can be an input or output.                                                                                                                                                                                                                                 |
| S5                         | 12    | 10   | Analog input or output | Source pin 5. Can be an input or output.                                                                                                                                                                                                                                 |
| S6                         | 11    | 9    | Analog input or output | Source pin 6. Can be an input or output.                                                                                                                                                                                                                                 |
| S7                         | 10    | 8    | Analog input or output | Source pin 7. Can be an input or output.                                                                                                                                                                                                                                 |
| S8                         | 9     | 7    | Analog input or output | Source pin 8. Can be an input or output.                                                                                                                                                                                                                                 |
| VDD                        | 13    | 11   | Power supply           | Positive power supply. This pin is the most positive power-supply potential. For reliable operation, connect a decoupling capacitor ranging from 0.1 $\mu$ F to 10 $\mu$ F between $V_{DD}$ and GND.                                                                     |
| VSS                        | 3     | 1    | Power supply           | Negative power supply. This pin is the most negative power-supply potential. In single-supply applications, this pin can be connected to ground. For reliable operation, connect a decoupling capacitor ranging from 0.1 $\mu$ F to 10 $\mu$ F between $V_{SS}$ and GND. |
| Thermal Pad <sup>(1)</sup> | -     | -    | Power supply           | Exposed Pad. The exposed pad is electrically connected to $V_{SS}$ internally. Connect EP to $V_{SS}$ to achieve rated thermal and ESD performance.                                                                                                                      |

(1) RUM and RRJ have the same package dimension, but different thermal pad dimension and lead finger length.

**MUX36D04: PW Package  
16-Pin TSSOP  
Top View**



**MUX36D04: RUM and RRJ Package  
16-Pin WQFN  
Top View**



RUM and RRJ have the same package dimension, but different thermal pad dimension and lead finger length.

### Pin Functions: MUX36D04

| PIN                        |       |      | FUNCTION               | DESCRIPTION                                                                                                                                                                                                                                                           |
|----------------------------|-------|------|------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME                       | TSSOP | WQFN |                        |                                                                                                                                                                                                                                                                       |
| A0                         | 1     | 15   | Digital input          | Address line 0                                                                                                                                                                                                                                                        |
| A1                         | 16    | 14   | Digital input          | Address line 1                                                                                                                                                                                                                                                        |
| DA                         | 8     | 6    | Analog input or output | Drain pin A. Can be an input or output.                                                                                                                                                                                                                               |
| DB                         | 9     | 7    | Analog input or output | Drain pin B. Can be an input or output.                                                                                                                                                                                                                               |
| EN                         | 2     | 16   | Digital input          | Active high digital input. When this pin is low, all switches are turned off. When this pin is high, the A[1:0] logic inputs determine which pair of switches is turned on.                                                                                           |
| GND                        | 15    | 13   | Power supply           | Ground (0 V) reference                                                                                                                                                                                                                                                |
| S1A                        | 4     | 2    | Analog input or output | Source pin 1A. Can be an input or output.                                                                                                                                                                                                                             |
| S2A                        | 5     | 3    | Analog input or output | Source pin 2A. Can be an input or output.                                                                                                                                                                                                                             |
| S3A                        | 6     | 4    | Analog input or output | Source pin 3A. Can be an input or output.                                                                                                                                                                                                                             |
| S4A                        | 7     | 5    | Analog input or output | Source pin 4A. Can be an input or output.                                                                                                                                                                                                                             |
| S1B                        | 13    | 11   | Analog input or output | Source pin 1B. Can be an input or output.                                                                                                                                                                                                                             |
| S2B                        | 12    | 10   | Analog input or output | Source pin 2B. Can be an input or output.                                                                                                                                                                                                                             |
| S3B                        | 11    | 9    | Analog input or output | Source pin 3B. Can be an input or output.                                                                                                                                                                                                                             |
| S4B                        | 10    | 8    | Analog input or output | Source pin 4B. Can be an input or output.                                                                                                                                                                                                                             |
| V <sub>DD</sub>            | 14    | 12   | Power supply           | Positive power supply. This pin is the most positive power supply potential. For reliable operation, connect a decoupling capacitor ranging from 0.1 μF to 10 μF between V <sub>DD</sub> and GND.                                                                     |
| V <sub>SS</sub>            | 3     | 1    | Power supply           | Negative power supply. This pin is the most negative power supply potential. In single-supply applications, this pin can be connected to ground. For reliable operation, connect a decoupling capacitor ranging from 0.1 μF to 10 μF between V <sub>SS</sub> and GND. |
| Thermal Pad <sup>(1)</sup> | -     | -    | Power supply           | Exposed Pad. The exposed pad is electrically connected to VSS internally. Connect EP to VSS to achieve rated thermal and ESD performance.                                                                                                                             |

(1) RUM and RRJ have the same package dimension, but different thermal pad dimension and lead finger length.

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                        |                                                           |                                   | MIN                   | MAX                   | UNIT |
|------------------------|-----------------------------------------------------------|-----------------------------------|-----------------------|-----------------------|------|
| Voltage                | Supply                                                    | V <sub>DD</sub>                   | −0.3                  | 40                    | V    |
|                        |                                                           | V <sub>SS</sub>                   | −40                   | 0.3                   |      |
|                        |                                                           | V <sub>DD</sub> − V <sub>SS</sub> |                       | 40                    |      |
|                        | Digital input pins: <sup>(2)</sup> EN, A0, A1, A2         |                                   | V <sub>SS</sub> − 0.3 | V <sub>DD</sub> + 0.3 | V    |
|                        | Analog input pins: <sup>(2)</sup> Sx, SxA, SxB, D, DA, DB |                                   | V <sub>SS</sub> − 2   | V <sub>DD</sub> + 2   | V    |
| Current <sup>(3)</sup> |                                                           |                                   | −30                   | 30                    | mA   |
| Temperature            | Operating, T <sub>A</sub>                                 |                                   | −55                   | 150                   | °C   |
|                        | Junction, T <sub>J</sub>                                  |                                   |                       | 150                   |      |
|                        | Storage, T <sub>stg</sub>                                 |                                   | −65                   | 150                   |      |

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Only one pin at a time

(3) Voltage limits are valid if current is limited to  $\pm 30$  mA.

### 7.2 ESD Ratings

|                                     |                                                                                | VALUE      | UNIT |
|-------------------------------------|--------------------------------------------------------------------------------|------------|------|
| $V_{(ESD)}$ Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | $\pm 2000$ | V    |
|                                     | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | $\pm 500$  |      |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 7.3 Recommended Operating Conditions

|                                                                     |               |  | MIN      | NOM | MAX      | UNIT |
|---------------------------------------------------------------------|---------------|--|----------|-----|----------|------|
| $V_{DD}$ <sup>(1)</sup> Positive power-supply voltage               | Dual supply   |  | 5        |     | 18       | V    |
|                                                                     | Single supply |  | 10       |     | 36       |      |
| $V_{SS}$ <sup>(2)</sup> Negative power-supply voltage (dual supply) |               |  | −5       |     | −18      | V    |
| $V_{DD} - V_{SS}$ Supply voltage                                    |               |  | 10       |     | 36       | V    |
| $V_S$ Source pins voltage <sup>(3)</sup>                            |               |  | $V_{SS}$ |     | $V_{DD}$ | V    |
| $V_D$ Drain pins voltage                                            |               |  | $V_{SS}$ |     | $V_{DD}$ | V    |
| $V_{EN}$ Enable pin voltage                                         |               |  | $V_{SS}$ |     | $V_{DD}$ | V    |
| $V_A$ Address pins voltage                                          |               |  | $V_{SS}$ |     | $V_{DD}$ | V    |
| $I_{CH}$ Channel current ( $T_A = 25^\circ\text{C}$ )               |               |  | −25      |     | 25       | mA   |
| $T_A$ Operating temperature                                         |               |  | −40      |     | 125      | °C   |

(1) When  $V_{SS} = 0$  V,  $V_{DD}$  can range from 10 V to 36 V.

(2)  $V_{DD}$  and  $V_{SS}$  can be any value as long as  $10\text{ V} \leq (V_{DD} - V_{SS}) \leq 36\text{ V}$ .

(3)  $V_S$  is the voltage on all S pins.

## 7.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | MUX36S08 and MUX36D04 |            |            | UNIT |
|-------------------------------|----------------------------------------------|-----------------------|------------|------------|------|
|                               |                                              | PW (TSSOP)            | RUM (WQFN) | RRJ (WQFN) |      |
|                               |                                              | 16 PINS               | 16 PINS    | 16 PINS    |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 103.8                 | 37.3       | 46.2       | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 36.8                  | 31.6       | 37.7       | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 49.8                  | 16.2       | 21.7       | °C/W |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 2.7                   | 0.5        | 0.7        | °C/W |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 49.1                  | 16.2       | 21.7       | °C/W |
| R <sub>θJC(bot)</sub>         | Junction-to-case (bottom) thermal resistance | N/A                   | 6.1        | 6.2        | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 7.5 Electrical Characteristics: Dual Supply

at T<sub>A</sub> = 25°C, V<sub>DD</sub> = 15 V, and V<sub>SS</sub> = –15 V (unless otherwise noted)

| PARAMETER           |                                         | TEST CONDITIONS                                                                          |                                  | MIN             | TYP   | MAX             | UNIT |
|---------------------|-----------------------------------------|------------------------------------------------------------------------------------------|----------------------------------|-----------------|-------|-----------------|------|
| ANALOG SWITCH       |                                         |                                                                                          |                                  |                 |       |                 |      |
| Analog signal range |                                         | T <sub>A</sub> = −40°C to +125°C                                                         |                                  | V <sub>SS</sub> |       | V <sub>DD</sub> | V    |
| R <sub>ON</sub>     | On-resistance                           | V <sub>S</sub> = 0 V, I <sub>CH</sub> = 1 mA                                             |                                  | 125             |       | 170             | Ω    |
|                     |                                         | V <sub>S</sub> = ±10 V, I <sub>CH</sub> = 1 mA                                           |                                  | 145             |       | 200             | Ω    |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +85°C  |                 |       | 230             |      |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +125°C |                 |       | 250             |      |
| ΔR <sub>ON</sub>    | On-resistance mismatch between channels | V <sub>S</sub> = ±10 V, I <sub>CH</sub> = 1 mA                                           |                                  | 2.4             |       | 6               | Ω    |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +85°C  |                 |       | 9               |      |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +125°C |                 |       | 11              |      |
| R <sub>FLAT</sub>   | On-resistance flatness                  | V <sub>S</sub> = 10 V, 0 V, −10 V                                                        |                                  | 2.4             |       | 6               | Ω    |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +85°C  |                 |       | 53              |      |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +125°C |                 |       | 58              |      |
| On-resistance drift |                                         | V <sub>S</sub> = 0 V                                                                     |                                  | 0.64            |       |                 | %/°C |
| I <sub>S(OFF)</sub> | Input leakage current                   | Switch state is off, V <sub>S</sub> = ±10 V, V <sub>D</sub> = ±10 V <sup>(1)</sup>       |                                  | −0.04           | 0.001 | 0.04            | nA   |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +85°C  | −0.15           |       | 0.15            |      |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +125°C | −1.9            |       | 1.9             |      |
| I <sub>D(OFF)</sub> | Output off leakage current              | Switch state is off, V <sub>S</sub> = ±10 V, V <sub>D</sub> = ±10 V <sup>(1)</sup>       |                                  | −0.1            | 0.005 | 0.1             | nA   |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +85°C  | −0.5            |       | 0.5             |      |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +125°C | −2              |       | 2               |      |
| I <sub>D(ON)</sub>  | Output on leakage current               | Switch state is on, V <sub>D</sub> = ±10 V, V <sub>S</sub> = floating                    |                                  | −0.1            | 0.008 | 0.1             | nA   |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +85°C  | −0.5            |       | 0.5             |      |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +125°C | −3.3            |       | 3.3             |      |
| I <sub>DL(ON)</sub> | Differential on-leakage current         | Switch state is on, V <sub>DA</sub> = V <sub>DB</sub> = ±10 V, V <sub>S</sub> = floating |                                  | −15             | 3     | 15              | pA   |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +85°C  | −100            |       | 100             |      |
|                     |                                         |                                                                                          | T <sub>A</sub> = −40°C to +125°C | −500            |       | 500             |      |
| LOGIC INPUT         |                                         |                                                                                          |                                  |                 |       |                 |      |
| V <sub>IH</sub>     | Logic voltage high                      |                                                                                          |                                  | 2               |       |                 | V    |
| V <sub>IL</sub>     | Logic voltage low                       |                                                                                          |                                  |                 |       | 0.8             | V    |

(1) When V<sub>S</sub> is positive, V<sub>D</sub> is negative, and vice versa.

## Electrical Characteristics: Dual Supply (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 15\text{ V}$ , and  $V_{SS} = -15\text{ V}$  (unless otherwise noted)

| PARAMETER                               |                              | TEST CONDITIONS                                                                                         |                                  | MIN  | TYP  | MAX  | UNIT |
|-----------------------------------------|------------------------------|---------------------------------------------------------------------------------------------------------|----------------------------------|------|------|------|------|
| I <sub>D</sub>                          | Input current                |                                                                                                         |                                  |      |      | 0.15 | μA   |
| SWITCH DYNAMICS <sup>(2)</sup>          |                              |                                                                                                         |                                  |      |      |      |      |
| t <sub>ON</sub>                         | Enable turn-on time          | V <sub>S</sub> = ±10 V, R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF                                  |                                  | 88   | 136  | ns   |      |
|                                         |                              |                                                                                                         | T <sub>A</sub> = −40°C to +85°C  |      | 144  |      |      |
|                                         |                              |                                                                                                         | T <sub>A</sub> = −40°C to +125°C |      | 151  |      |      |
| t <sub>OFF</sub>                        | Enable turn-off time         | V <sub>S</sub> = ±10 V, R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF                                  |                                  | 63   | 75   | ns   |      |
|                                         |                              |                                                                                                         | T <sub>A</sub> = −40°C to +85°C  |      | 83   |      |      |
|                                         |                              |                                                                                                         | T <sub>A</sub> = −40°C to +125°C |      | 90   |      |      |
| t <sub>t</sub>                          | Transition time              | V <sub>S</sub> = 10 V, R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF                                   |                                  | 92   | 143  | ns   |      |
|                                         |                              |                                                                                                         | T <sub>A</sub> = −40°C to +85°C  |      | 151  |      |      |
|                                         |                              |                                                                                                         | T <sub>A</sub> = −40°C to +125°C |      | 157  |      |      |
| t <sub>BBM</sub>                        | Break-before-make time delay | V <sub>S</sub> = 10 V, R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF, T <sub>A</sub> = −40°C to +125°C |                                  | 30   | 54   | ns   |      |
| Q <sub>J</sub>                          | Charge injection             | C <sub>L</sub> = 1 nF, R <sub>S</sub> = 0 Ω                                                             | V <sub>S</sub> = 0 V             | 0.3  |      | pC   |      |
|                                         |                              |                                                                                                         | V <sub>S</sub> = −15 V to +15 V  | ±0.6 |      |      |      |
|                                         | Off-isolation                | R <sub>L</sub> = 50 Ω, V <sub>S</sub> = 1 V <sub>RMS</sub> , f = 1 MHz                                  | Nonadjacent channel to D, DA, DB | −96  |      | dB   |      |
|                                         |                              |                                                                                                         | Adjacent channel to D, DA, DB    | −85  |      |      |      |
|                                         | Channel-to-channel crosstalk | R <sub>L</sub> = 50 Ω, V <sub>S</sub> = 1 V <sub>RMS</sub> , f = 1 MHz                                  | Nonadjacent channels             | −96  |      | dB   |      |
|                                         |                              |                                                                                                         | Adjacent channels                | −88  |      |      |      |
| C <sub>S(OFF)</sub>                     | Input off-capacitance        | f = 1 MHz, V <sub>S</sub> = 0 V                                                                         |                                  | 2.4  | 2.9  | pF   |      |
| C <sub>D(OFF)</sub>                     | Output off-capacitance       | f = 1 MHz, V <sub>S</sub> = 0 V                                                                         | MUX36S08                         | 7.5  | 8.4  | pF   |      |
|                                         |                              |                                                                                                         | MUX36D04                         | 4.3  | 5    |      |      |
| C <sub>S(ON)</sub> , C <sub>D(ON)</sub> | Output on-capacitance        | f = 1 MHz, V <sub>S</sub> = 0 V                                                                         | MUX36S08                         | 9.4  | 10.6 | pF   |      |
|                                         |                              |                                                                                                         | MUX36D04                         | 6.7  | 7.7  |      |      |
| POWER SUPPLY                            |                              |                                                                                                         |                                  |      |      |      |      |
| V <sub>DD</sub>                         | supply current               | All V <sub>A</sub> = 0 V or 3.3 V, V <sub>S</sub> = 0 V, V <sub>EN</sub> = 3.3 V                        |                                  | 45   | 59   | μA   |      |
|                                         |                              |                                                                                                         | T <sub>A</sub> = −40°C to +85°C  |      | 62   |      |      |
|                                         |                              |                                                                                                         | T <sub>A</sub> = −40°C to +125°C |      | 83   |      |      |
| V <sub>SS</sub>                         | supply current               | All V <sub>A</sub> = 0 V or 3.3 V, V <sub>S</sub> = 0 V, V <sub>EN</sub> = 3.3 V                        |                                  | 25   | 34   | μA   |      |
|                                         |                              |                                                                                                         | T <sub>A</sub> = −40°C to +85°C  |      | 37   |      |      |
|                                         |                              |                                                                                                         | T <sub>A</sub> = −40°C to +125°C |      | 57   |      |      |

(2) Specified by design, not subject to production testing.

## 7.6 Electrical Characteristics: Single Supply

at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 12\text{ V}$ , and  $V_{SS} = 0\text{ V}$  (unless otherwise noted)

| PARAMETER                                     |                              | TEST CONDITIONS                                                                                                                             |                                  | MIN             | TYP   | MAX             | UNIT |
|-----------------------------------------------|------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------|-----------------|-------|-----------------|------|
| ANALOG SWITCH                                 |                              |                                                                                                                                             |                                  |                 |       |                 |      |
| Analog signal range                           |                              | T <sub>A</sub> = −40°C to +125°C                                                                                                            |                                  | V <sub>SS</sub> |       | V <sub>DD</sub> | V    |
| R <sub>ON</sub>                               | On-resistance                | V <sub>S</sub> = 10 V, I <sub>CH</sub> = 1 mA                                                                                               |                                  | 235             |       | 340             | Ω    |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +85°C  | 390             |       |                 |      |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +125°C | 430             |       |                 |      |
| ΔR <sub>ON</sub>                              | On-resistance match          | V <sub>S</sub> = 10 V, I <sub>CH</sub> = 1 mA                                                                                               |                                  | 3.1             |       | 12              | Ω    |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +85°C  | 19              |       |                 |      |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +125°C | 23              |       |                 |      |
| On-resistance drift                           |                              | V <sub>S</sub> = 10 V                                                                                                                       |                                  | 1.13            |       |                 | %/°C |
| I <sub>S(OFF)</sub>                           | Input leakage current        | Switch state is off,<br>V <sub>S</sub> = 1 V and V <sub>D</sub> = 10 V,<br>or V <sub>S</sub> = 10 V and V <sub>D</sub> = 1 V <sup>(1)</sup> |                                  | −0.04           | 0.001 | 0.04            | nA   |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +85°C  | −0.15           |       | 0.15            |      |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +125°C | −1.9            |       | 1.9             |      |
| I <sub>D(OFF)</sub>                           | Output off leakage current   | Switch state is off,<br>V <sub>S</sub> = 1 V and V <sub>D</sub> = 10 V,<br>or V <sub>S</sub> = 10 V and V <sub>D</sub> = 1 V <sup>(1)</sup> |                                  | −0.1            | 0.005 | 0.1             | nA   |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +85°C  | −0.5            |       | 0.5             |      |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +125°C | −2              |       | 2               |      |
| I <sub>D(ON)</sub>                            | Output on leakage current    | Switch state is on,<br>V <sub>D</sub> = 1 V and 10 V,<br>V <sub>S</sub> = floating                                                          |                                  | −0.1            | 0.008 | 0.1             | nA   |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +85°C  | −0.5            |       | 0.5             |      |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +125°C | −3.3            |       | 3.3             |      |
| LOGIC INPUT                                   |                              |                                                                                                                                             |                                  |                 |       |                 |      |
| V <sub>IH</sub>                               | Logic voltage high           |                                                                                                                                             |                                  | 2.0             |       |                 | V    |
| V <sub>IL</sub>                               | Logic voltage low            |                                                                                                                                             |                                  |                 |       | 0.8             | V    |
| I <sub>D</sub>                                | Input current                |                                                                                                                                             |                                  |                 |       | 0.15            | μA   |
| SWITCH DYNAMIC CHARACTERISTICS <sup>(2)</sup> |                              |                                                                                                                                             |                                  |                 |       |                 |      |
| t <sub>ON</sub>                               | Enable turn-on time          | V <sub>S</sub> = 8 V, R <sub>L</sub> = 300 Ω,<br>C <sub>L</sub> = 35 pF                                                                     |                                  | 85              |       | 140             | ns   |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +85°C  | 145             |       |                 |      |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +125°C | 149             |       |                 |      |
| t <sub>OFF</sub>                              | Enable turn-off time         | V <sub>S</sub> = 8 V, R <sub>L</sub> = 300 Ω,<br>C <sub>L</sub> = 35 pF                                                                     |                                  | 48              |       | 83              | ns   |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +85°C  | 94              |       |                 |      |
|                                               |                              |                                                                                                                                             | T <sub>A</sub> = −40°C to +125°C | 102             |       |                 |      |
| t <sub>t</sub>                                | Transition time              | V <sub>S</sub> = 8 V, C <sub>L</sub> = 35 pF                                                                                                |                                  | 87              |       | 147             | ns   |
|                                               |                              | V <sub>S</sub> = 8 V, R <sub>L</sub> = 300 Ω,<br>C <sub>L</sub> = 35 pF                                                                     | T <sub>A</sub> = −40°C to +85°C  | 153             |       |                 |      |
|                                               |                              | V <sub>S</sub> = 8 V, R <sub>L</sub> = 300 Ω,<br>C <sub>L</sub> = 35 pF                                                                     | T <sub>A</sub> = −40°C to +125°C | 155             |       |                 |      |
| t <sub>BBM</sub>                              | Break-before-make time delay | V <sub>S</sub> = 8 V, R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF, T <sub>A</sub> = −40°C to +125°C                                      |                                  | 30              | 54    |                 | ns   |
| Q <sub>J</sub>                                | Charge injection             | C <sub>L</sub> = 1 nF, R <sub>S</sub> = 0 Ω                                                                                                 | V <sub>S</sub> = 6 V             | 0.15            |       |                 | pC   |
|                                               |                              |                                                                                                                                             | V <sub>S</sub> = 0 V to 12 V,    | ±0.4            |       |                 |      |
|                                               | Off-isolation                | R <sub>L</sub> = 50 Ω, V <sub>S</sub> = 1 V <sub>RMS</sub> ,<br>f = 1 MHz                                                                   | Nonadjacent channel to D, DA, DB | -96             |       |                 | dB   |
|                                               |                              |                                                                                                                                             | Adjacent channel to D, DA, DB    | -85             |       |                 |      |
|                                               | Channel-to-channel crosstalk | R <sub>L</sub> = 50 Ω, V <sub>S</sub> = 1 V <sub>RMS</sub> ,<br>f = 1 MHz                                                                   | Nonadjacent channels             | −96             |       |                 | dB   |
|                                               |                              |                                                                                                                                             | Adjacent channels                | -88             |       |                 |      |
| C <sub>S(OFF)</sub>                           | Input off-capacitance        | f = 1 MHz, V <sub>S</sub> = 6 V                                                                                                             |                                  |                 | 2.7   | 3.2             | pF   |
| C <sub>D(OFF)</sub>                           | Output off-capacitance       | f = 1 MHz, V <sub>S</sub> = 6 V                                                                                                             | MUX36S08                         | 9.1             |       | 10              | pF   |
|                                               |                              |                                                                                                                                             | MUX36D04                         | 5               |       | 5.7             |      |
| C <sub>S(ON)</sub> ,<br>C <sub>D(ON)</sub>    | Output on-capacitance        | f = 1 MHz, V <sub>S</sub> = 6 V                                                                                                             | MUX36S08                         | 10.8            |       | 12              | pF   |
|                                               |                              |                                                                                                                                             | MUX36D04                         | 6.9             |       | 8               |      |

(1) When  $V_S$  is 1 V,  $V_D$  is 10 V, and vice versa.

(2) Specified by design; not subject to production testing.

## Electrical Characteristics: Single Supply (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 12\text{ V}$ , and  $V_{SS} = 0\text{ V}$  (unless otherwise noted)

| PARAMETER               | TEST CONDITIONS                                                                            | MIN                                               | TYP | MAX | UNIT          |
|-------------------------|--------------------------------------------------------------------------------------------|---------------------------------------------------|-----|-----|---------------|
| <b>POWER SUPPLY</b>     |                                                                                            |                                                   |     |     |               |
| $V_{DD}$ supply current | All $V_A = 0\text{ V}$ or $3.3\text{ V}$ ,<br>$V_S = 0\text{ V}$ , $V_{EN} = 3.3\text{ V}$ |                                                   | 42  | 53  | $\mu\text{A}$ |
|                         |                                                                                            | $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$  |     | 56  |               |
|                         |                                                                                            | $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ |     | 77  |               |
| $V_{SS}$ supply current | All $V_A = 0\text{ V}$ or $3.3\text{ V}$ ,<br>$V_S = 0\text{ V}$ , $V_{EN} = 3.3\text{ V}$ |                                                   | 23  | 31  | $\mu\text{A}$ |
|                         |                                                                                            | $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$  |     | 38  |               |
|                         |                                                                                            | $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$ |     | 51  |               |

## 7.7 Typical Characteristics

at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 15\text{ V}$ , and  $V_{SS} = -15\text{ V}$  (unless otherwise noted)

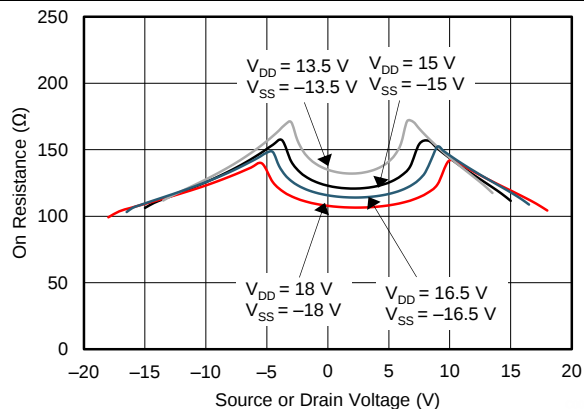
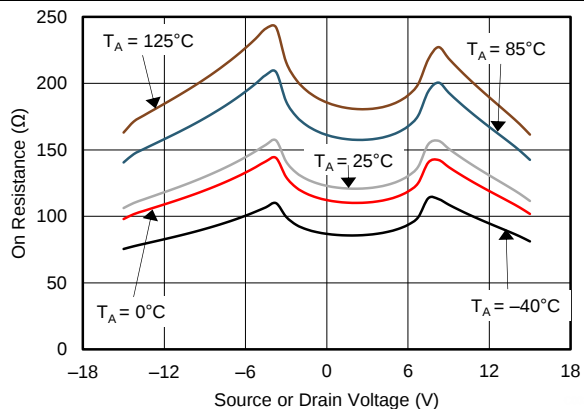


图 1. On-Resistance vs Source or Drain Voltage



$V_{DD} = 15\text{ V}$ ,  $V_{SS} = -15\text{ V}$

图 2. On-Resistance vs Source or Drain Voltage

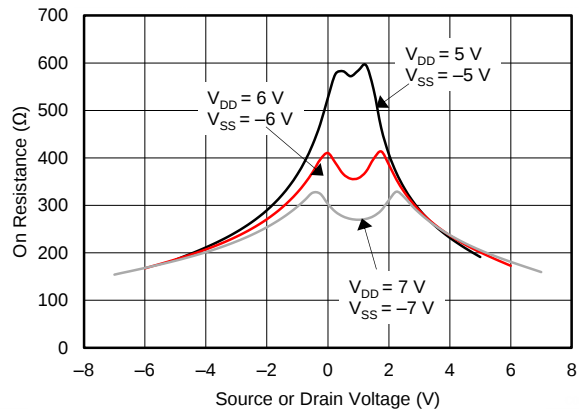
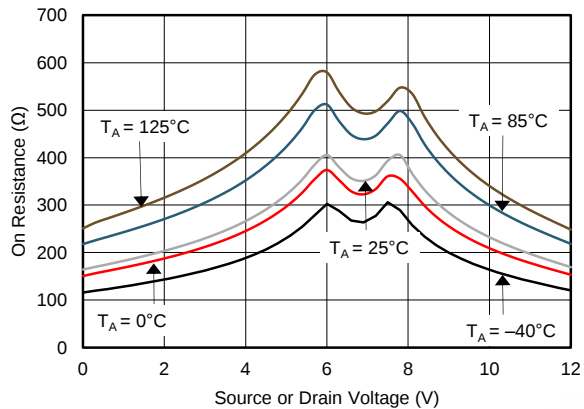


图 3. On-Resistance vs Source or Drain Voltage



$V_{DD} = 12\text{ V}$ ,  $V_{SS} = 0\text{ V}$

图 4. On-Resistance vs Source or Drain Voltage

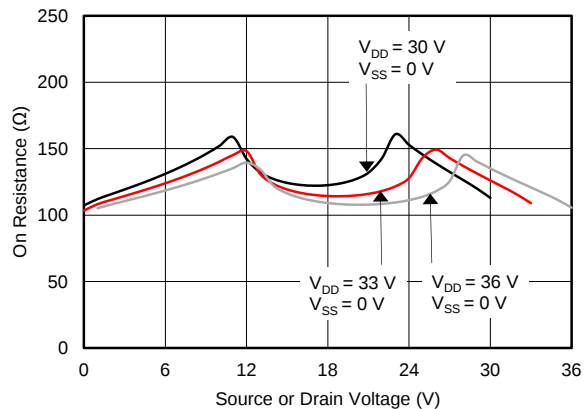


图 5. On-Resistance vs Source or Drain Voltage

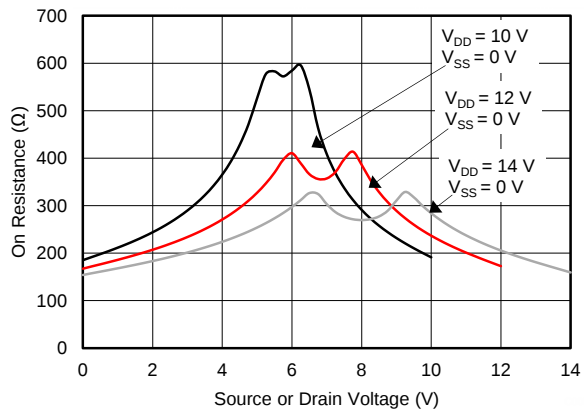
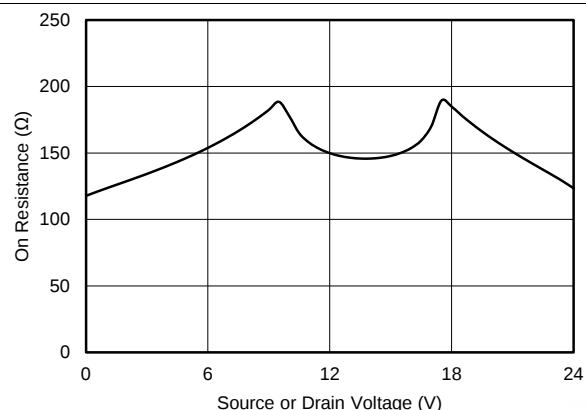


图 6. On-Resistance vs Source or Drain Voltage

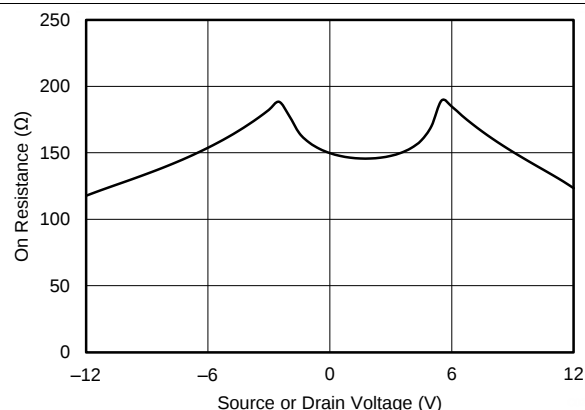
## Typical Characteristics (接下页)

at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 15\text{ V}$ , and  $V_{SS} = -15\text{ V}$  (unless otherwise noted)



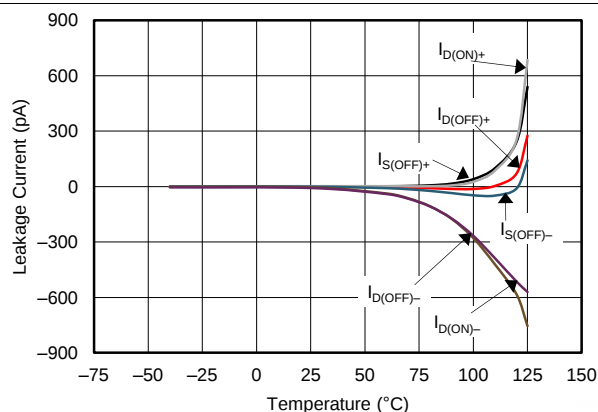
$V_{DD} = 24\text{ V}$ ,  $V_{SS} = 0\text{ V}$

图 7. On-Resistance vs Source or Drain Voltage



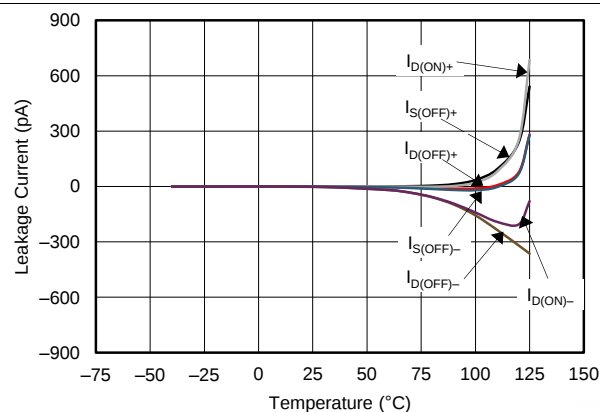
$V_{DD} = 12\text{ V}$ ,  $V_{SS} = -12\text{ V}$

图 8. On-Resistance vs Source or Drain Voltage



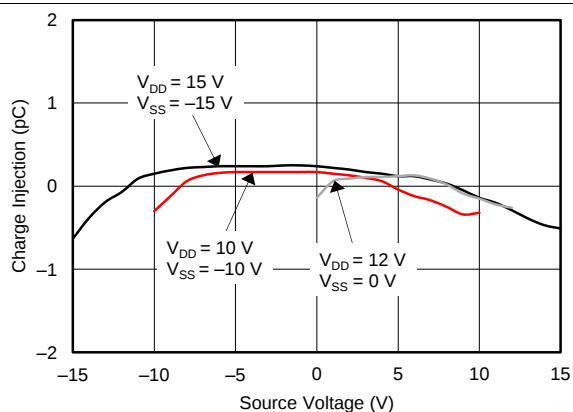
$V_{DD} = 15\text{ V}$ ,  $V_{SS} = -15\text{ V}$

图 9. Leakage Current vs Temperature



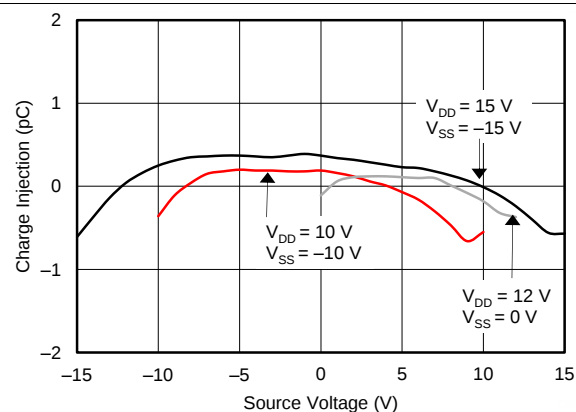
$V_{DD} = 12\text{ V}$ ,  $V_{SS} = 0\text{ V}$

图 10. Leakage Current vs Temperature



MUX36S08, source-to-drain

图 11. Charge Injection vs Source Voltage

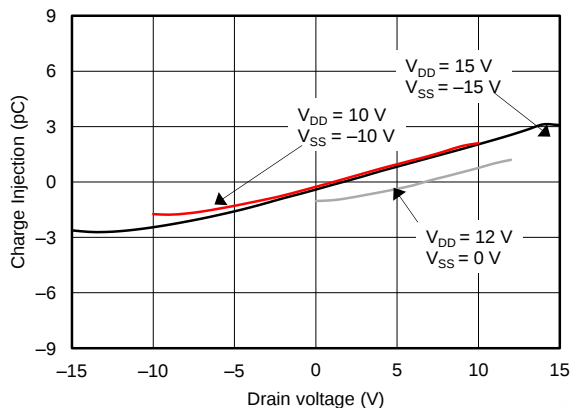


MUX36D04, source-to-drain

图 12. Charge Injection vs Source Voltage

## Typical Characteristics (接下页)

at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 15\text{ V}$ , and  $V_{SS} = -15\text{ V}$  (unless otherwise noted)



Drain-to-source

图 13. Charge Injection vs Source or Drain Voltage

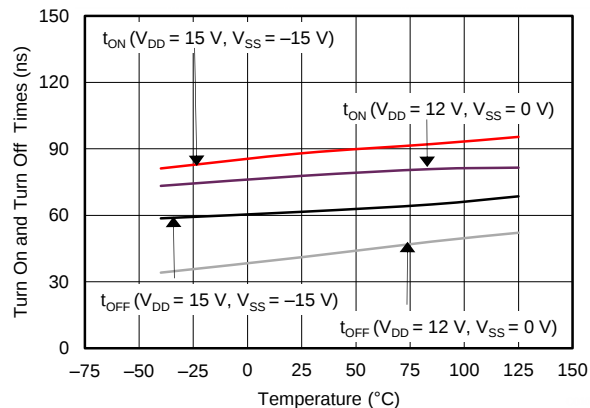


图 14. Turn-On and Turn-Off Times vs Temperature

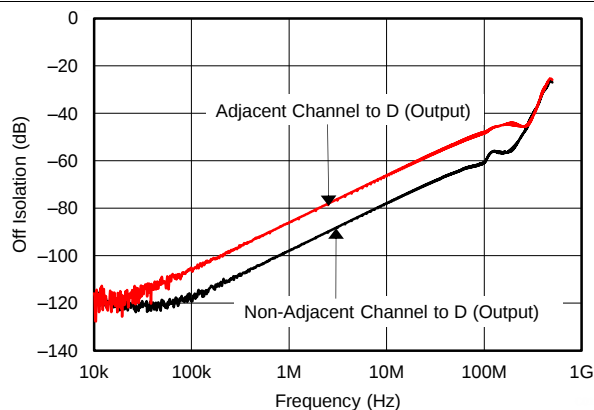


图 15. Off Isolation vs Frequency

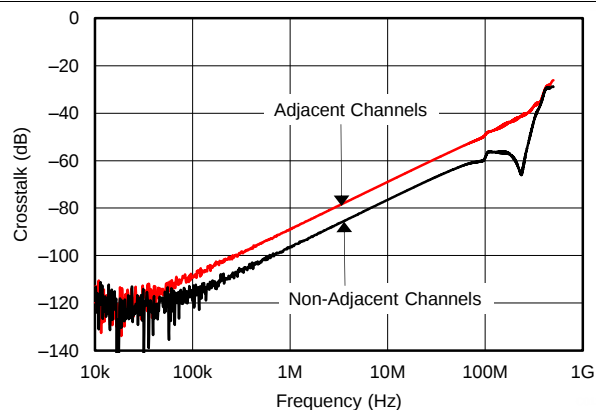


图 16. Crosstalk vs Frequency

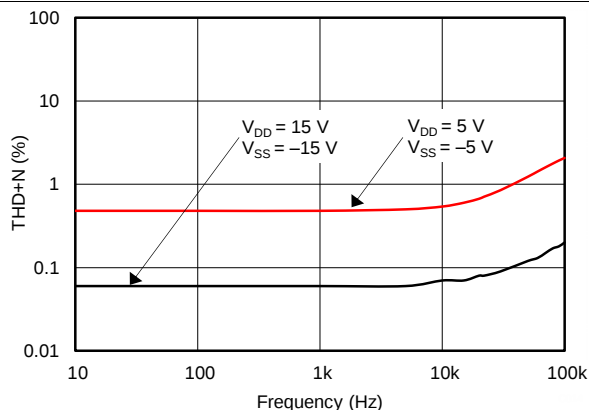


图 17. THD+N vs Frequency

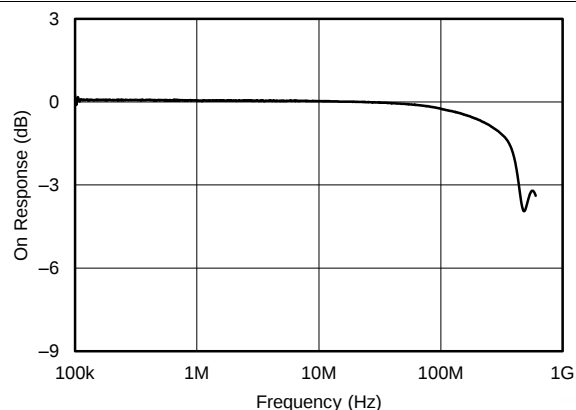
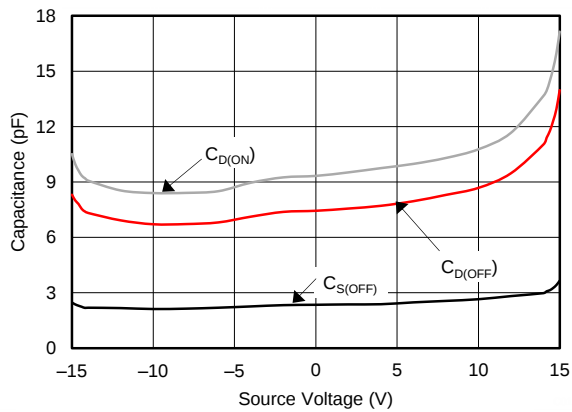


图 18. On Response vs Frequency

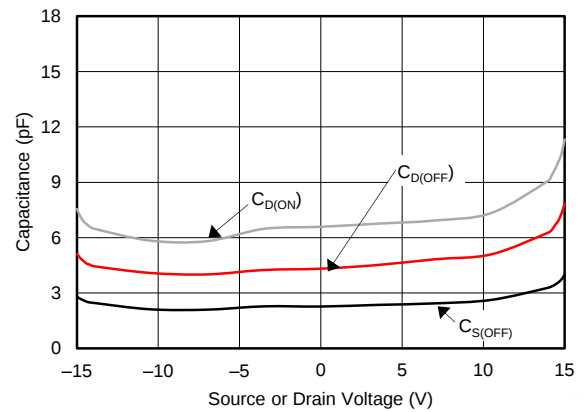
## Typical Characteristics (接下页)

at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 15\text{ V}$ , and  $V_{SS} = -15\text{ V}$  (unless otherwise noted)



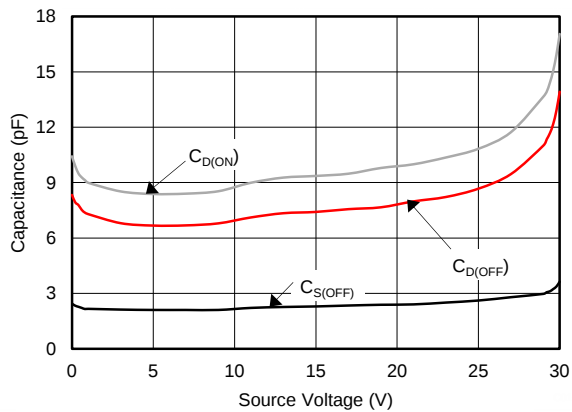
MUX36S08,  $V_{DD} = 15\text{ V}$ ,  $V_{SS} = -15\text{ V}$

图 19. Capacitance vs Source Voltage



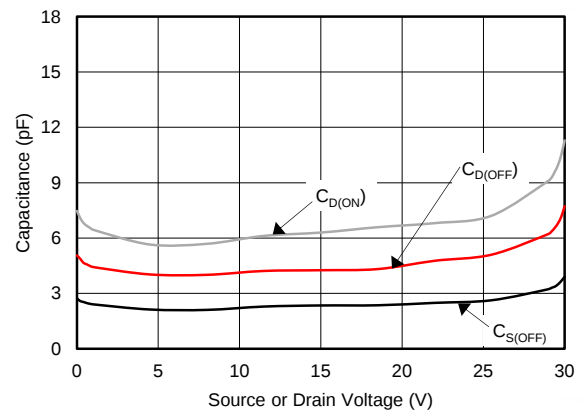
MUX36D04,  $V_{DD} = 15\text{ V}$ ,  $V_{SS} = -15\text{ V}$

图 20. Capacitance vs Source Voltage



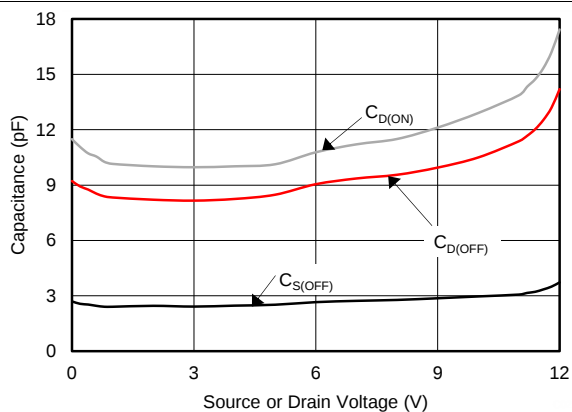
MUX36S08,  $V_{DD} = 30\text{ V}$ ,  $V_{SS} = 0\text{ V}$

图 21. Capacitance vs Source Voltage



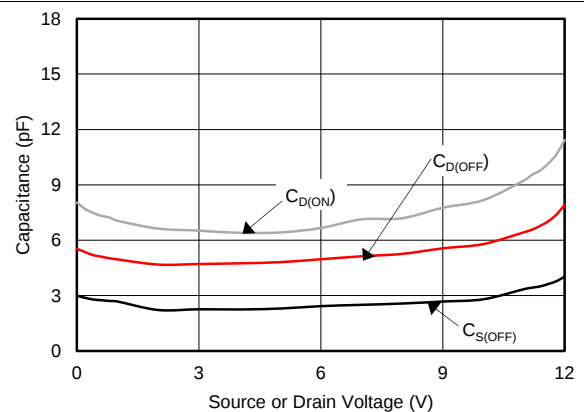
MUX36D04,  $V_{DD} = 30\text{ V}$ ,  $V_{SS} = 0\text{ V}$

图 22. Capacitance vs Source Voltage



MUX36S08,  $V_{DD} = 12\text{ V}$ ,  $V_{SS} = 0\text{ V}$

图 23. Capacitance vs Source Voltage



MUX36D04,  $V_{DD} = 12\text{ V}$ ,  $V_{SS} = 0\text{ V}$

图 24. Capacitance vs Source Voltage

## Typical Characteristics (接下页)

at  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 15\text{ V}$ , and  $V_{SS} = -15\text{ V}$  (unless otherwise noted)

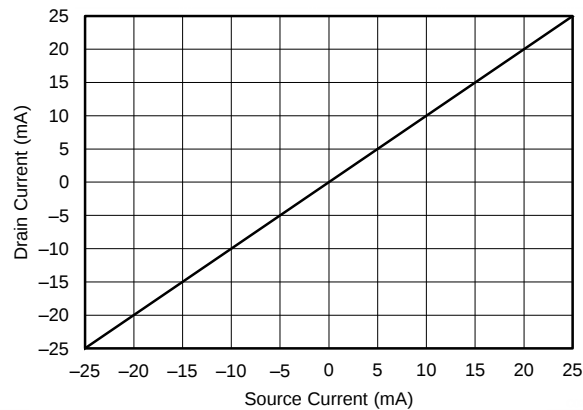


图 25. Source Current vs Drain Current

## 8 Parameter Measurement Information

### 8.1 Truth Tables

表 1 和 表 2 show the truth tables for the MUX36S08 and MUX36D04, respectively.

表 1. MUX36S08 Truth Table

| EN | A2               | A1               | A0               | STATE                |
|----|------------------|------------------|------------------|----------------------|
| 0  | X <sup>(1)</sup> | X <sup>(1)</sup> | X <sup>(1)</sup> | All channels are off |
| 1  | 0                | 0                | 0                | Channel 1            |
| 1  | 0                | 0                | 1                | Channel 2            |
| 1  | 0                | 1                | 0                | Channel 3            |
| 1  | 0                | 1                | 1                | Channel 4            |
| 1  | 1                | 0                | 0                | Channel 5            |
| 1  | 1                | 0                | 1                | Channel 6            |
| 1  | 1                | 1                | 0                | Channel 7            |
| 1  | 1                | 1                | 1                | Channel 8            |

(1) X denotes *don't care*..

表 2. MUX36D04 Truth Table

| EN | A1               | A0               | STATE                |
|----|------------------|------------------|----------------------|
| 0  | X <sup>(1)</sup> | X <sup>(1)</sup> | All channels are off |
| 1  | 0                | 0                | Channels 1A and 1B   |
| 1  | 0                | 1                | Channels 2A and 2B   |
| 1  | 1                | 0                | Channels 3A and 3B   |
| 1  | 1                | 1                | Channels 4A and 4B   |

(1) X denotes *don't care*.

## 8.2 On-Resistance

The on-resistance of the MUX36xxx is the ohmic resistance across the source (Sx, SxA, or SxB) and drain (D, DA, or DB) pins of the device. The on-resistance varies with input voltage and supply voltage. The symbol  $R_{ON}$  is used to denote on-resistance. The measurement setup used to measure  $R_{ON}$  is shown in 图 26. Voltage (V) and current ( $I_{CH}$ ) are measured using this setup, and  $R_{ON}$  is computed as shown in 公式 1:

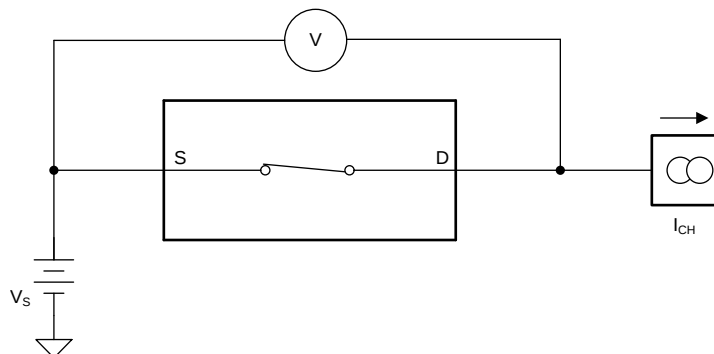


图 26. On-Resistance Measurement Setup

$$R_{ON} = V / I_{CH} \quad (1)$$

## 8.3 Off-Leakage Current

There are two types of leakage currents associated with a switch during the off state:

1. Source off-leakage current
2. Drain off-leakage current

Source leakage current is defined as the leakage current flowing into or out of the source pin when the switch is off. This current is denoted by the symbol  $I_{S(OFF)}$ .

Drain leakage current is defined as the leakage current flowing into or out of the drain pin when the switch is off. This current is denoted by the symbol  $I_{D(OFF)}$ .

The setup used to measure both off-leakage currents is shown in 图 27

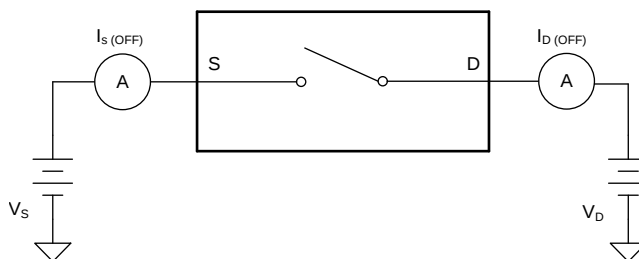


图 27. Off-Leakage Measurement Setup

## 8.4 On-Leakage Current

On-leakage current is defined as the leakage current that flows into or out of the drain pin when the switch is in the on state. The source pin is left floating during the measurement. 图 28 shows the circuit used for measuring the on-leakage current, denoted by  $I_{D(ON)}$ .

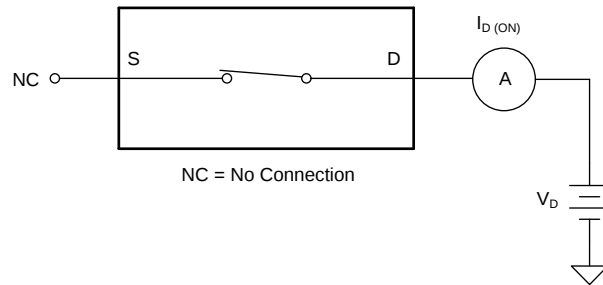


图 28. On-Leakage Measurement Setup

## 8.5 Differential On-Leakage Current

In case of a differential signal, the on-leakage current is defined as the differential leakage current that flows into or out of the drain pins when the switches is in the on state. The source pins are left floating during the measurement. 图 29 shows the circuit used for measuring the on-leakage current on each signal path, denoted by  $I_{DA(ON)}$  and  $I_{DB(ON)}$ . The absolute difference between these two current is defined as the differential on-leakage current  $I_{DL(ON)}$ .

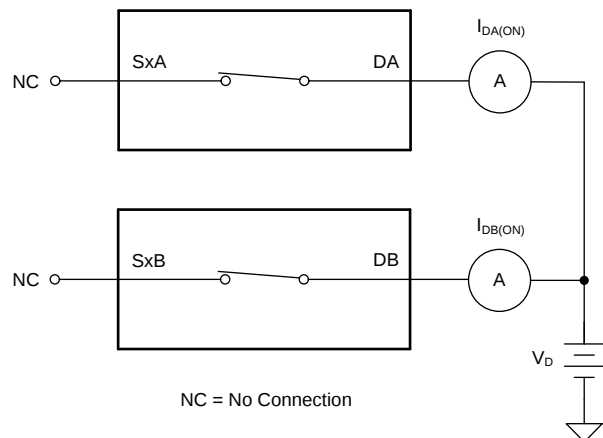


图 29. Differential On-Leakage Measurement Setup

## 8.6 Transition Time

Transition time is defined as the time taken by the output of the MUX36xxx to rise or fall to 90% of the transition after the digital address signal has fallen or risen to 50% of the transition. 图 30 shows the setup used to measure transition time, denoted by the symbol  $t_t$ .

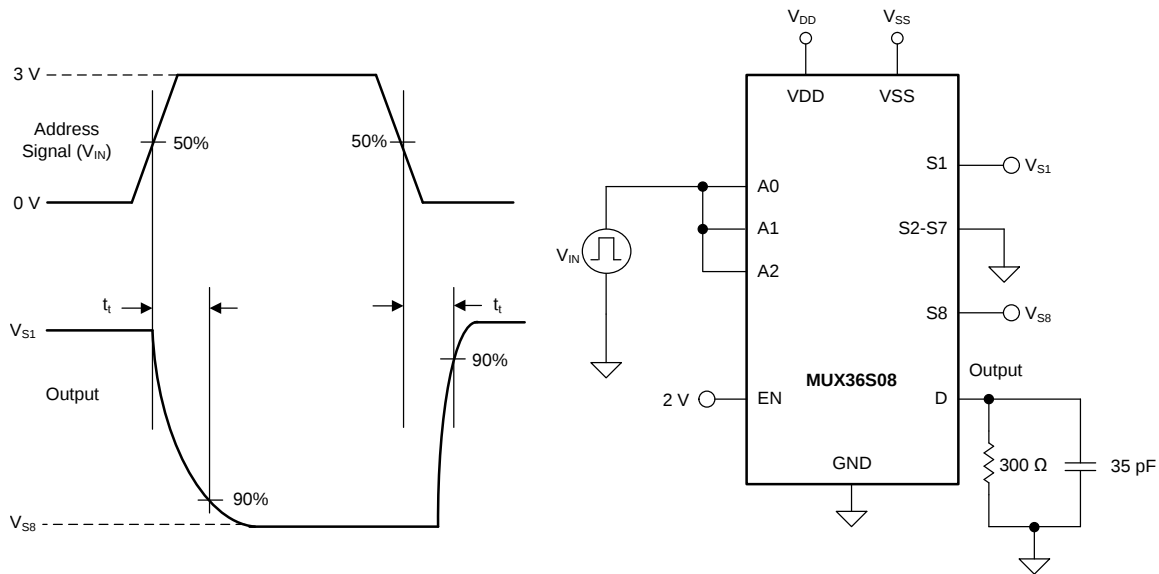


图 30. Transition-Time Measurement Setup

## 8.7 Break-Before-Make Delay

Break-before-make delay is a safety feature that prevents two inputs from connecting when the MUX36xxx is switching. The MUX36xxx output first breaks from the on-state switch before making the connection with the next on-state switch. The time delay between the *break* and the *make* is known as break-before-make delay. 图 31 shows the setup used to measure break-before-make delay, denoted by the symbol  $t_{BBM}$ .

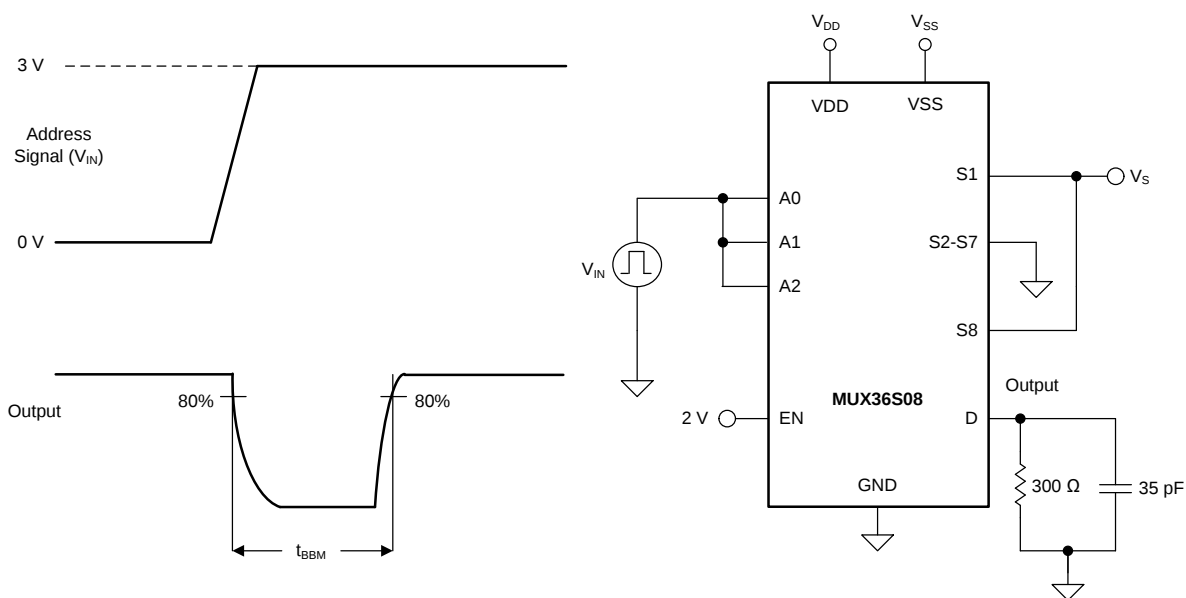


图 31. Break-Before-Make Delay Measurement Setup

## 8.8 Turn-On and Turn-Off Time

Turn-on time is defined as the time taken by the output of the MUX36xxx to rise to a 90% final value after the enable signal has risen to a 50% final value. 图 32 shows the setup used to measure turn-on time. Turn-on time is denoted by the symbol  $t_{ON}$ .

Turn off time is defined as the time taken by the output of the MUX36xxx to fall to a 10% initial value after the enable signal has fallen to a 50% initial value. 图 32 shows the setup used to measure turn-off time. Turn-off time is denoted by the symbol  $t_{OFF}$ .

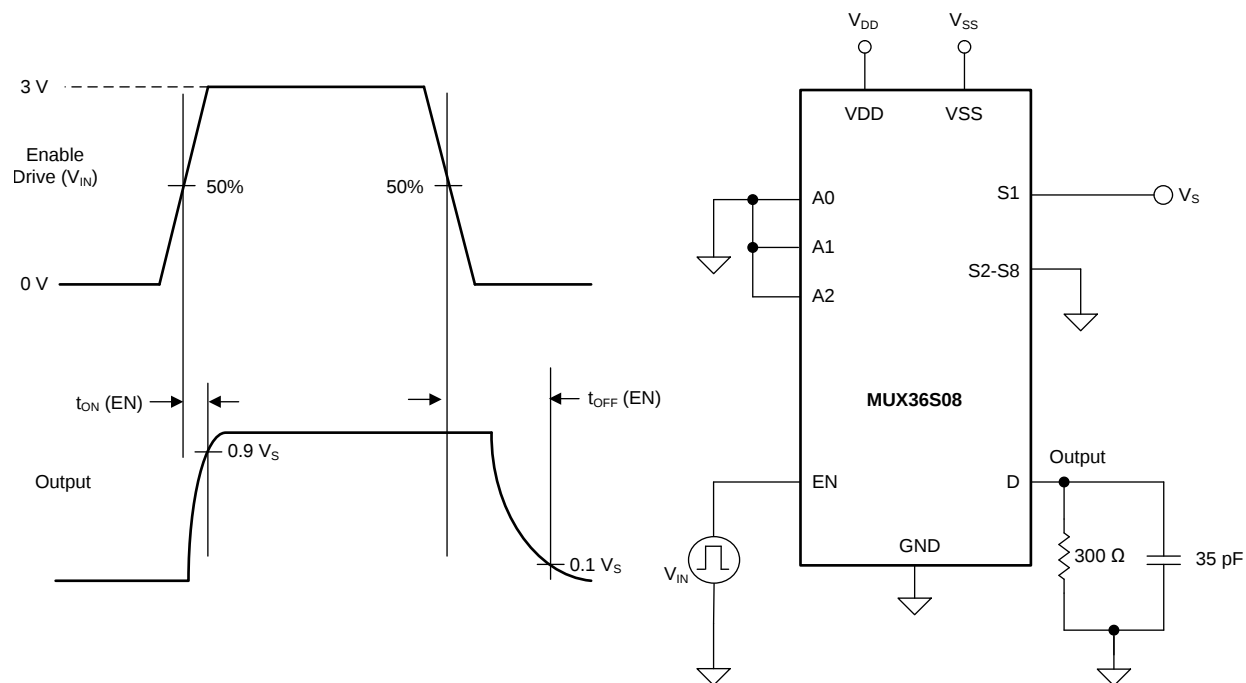


图 32. Turn-On and Turn-Off Time Measurement Setup

## 8.9 Charge Injection

The MUX36xxx have a simple transmission-gate topology. Any mismatch in capacitance between the NMOS and PMOS transistors results in a charge injected into the drain or source during the falling or rising edge of the gate signal. The amount of charge injected into the source or drain of the device is known as charge injection, and is denoted by the symbol  $Q_{\text{INJ}}$ . 图 33 shows the setup used to measure charge injection.

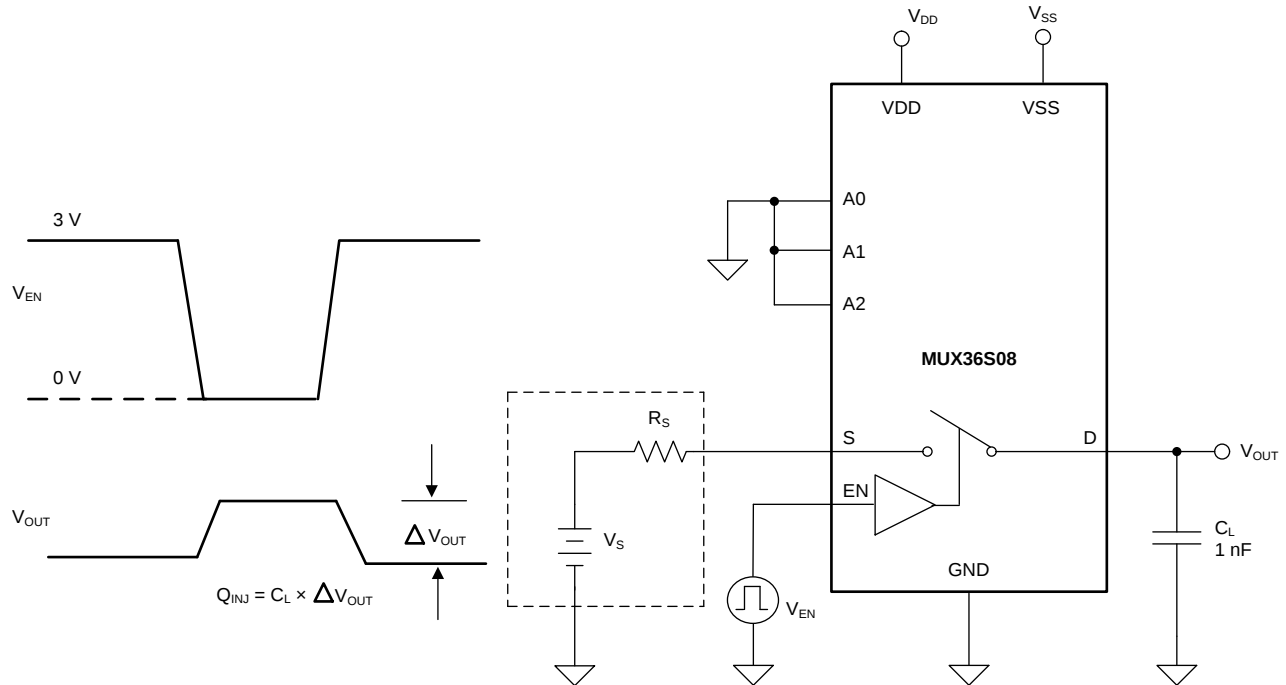


图 33. Charge-Injection Measurement Setup

## 8.10 Off Isolation

Off isolation is defined as the voltage at the drain pin (D, DA, or DB) of the MUX36xxx when a  $1\text{-}V_{\text{RMS}}$  signal is applied to the source pin (Sx, SxA, or SxB) of an off-channel. 图 34 shows the setup used to measure off isolation. Use 公式 2 to compute off isolation.

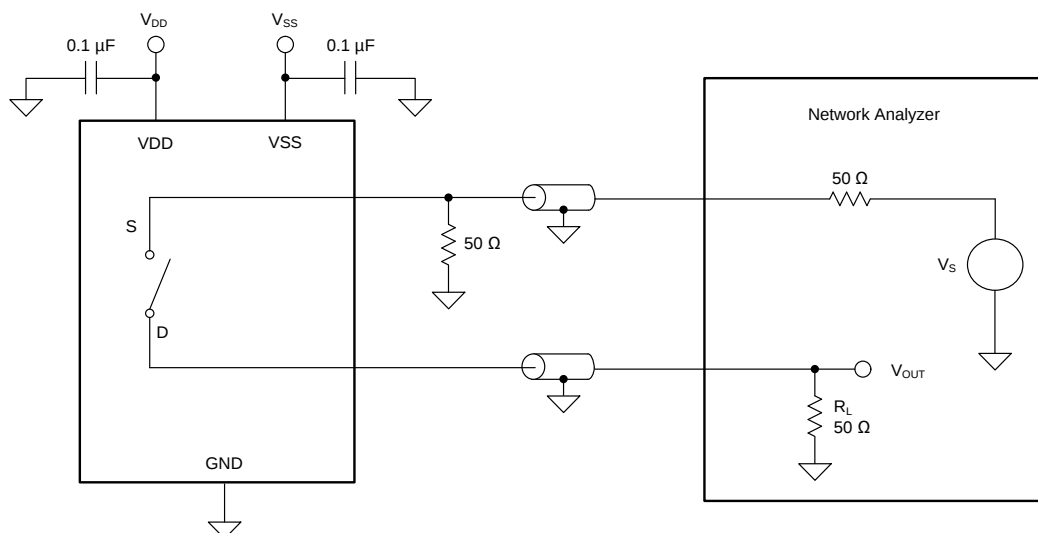


图 34. Off Isolation Measurement Setup

$$\text{Off Isolation} = 20 \cdot \text{Log} \left( \frac{V_{\text{OUT}}}{V_{\text{S}}} \right) \quad (2)$$

## 8.11 Channel-to-Channel Crosstalk

Channel-to-channel crosstalk is defined as the voltage at the source pin (Sx, SxA, or SxB) of an off-channel, when a  $1\text{-}V_{\text{RMS}}$  signal is applied at the source pin of an on-channel. 图 35 shows the setup used to measure, and 公式 3 is the equation used to compute, channel-to-channel crosstalk.

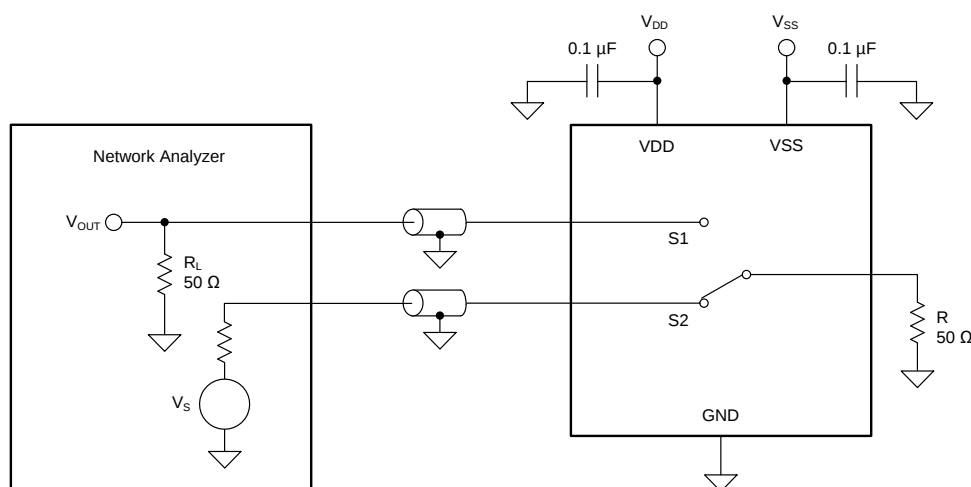


图 35. Channel-to-Channel Crosstalk Measurement Setup

$$\text{Channel-to-Channel Crosstalk} = 20 \cdot \text{Log} \left( \frac{V_{\text{OUT}}}{V_{\text{S}}} \right) \quad (3)$$

## 8.12 Bandwidth

Bandwidth is defined as the range of frequencies that are attenuated by < 3 dB when the input is applied to the source pin of an on-channel, and the output is measured at the drain pin of the MUX36xxx. 图 36 shows the setup used to measure bandwidth of the mux. Use 公式 4 to compute the attenuation.

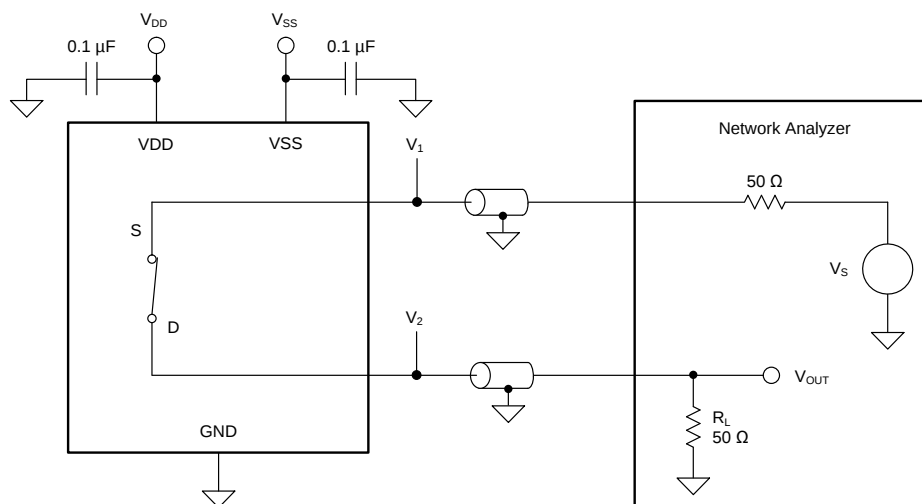


图 36. Bandwidth Measurement Setup

$$\text{Attenuation} = 20 \cdot \log\left(\frac{V_2}{V_1}\right) \quad (4)$$

## 8.13 THD + Noise

The total harmonic distortion (THD) of a signal is a measurement of the harmonic distortion, and is defined as the ratio of the sum of the powers of all harmonic components to the power of the fundamental frequency at the mux output. The on-resistance of the MUX36xxx varies with the amplitude of the input signal and results in distortion when the drain pin is connected to a low-impedance load. Total harmonic distortion plus noise is denoted as THD+N. 图 37 shows the setup used to measure THD+N of the MUX36xxx.

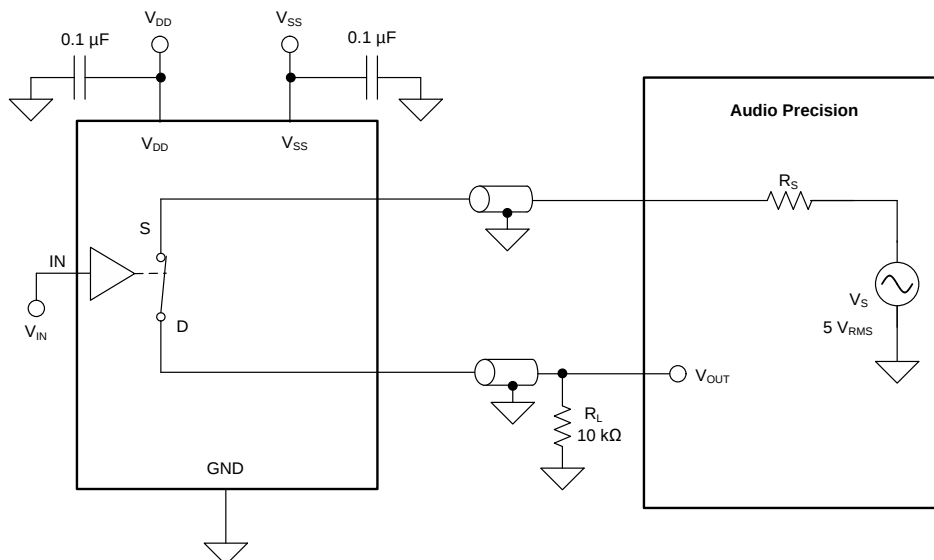


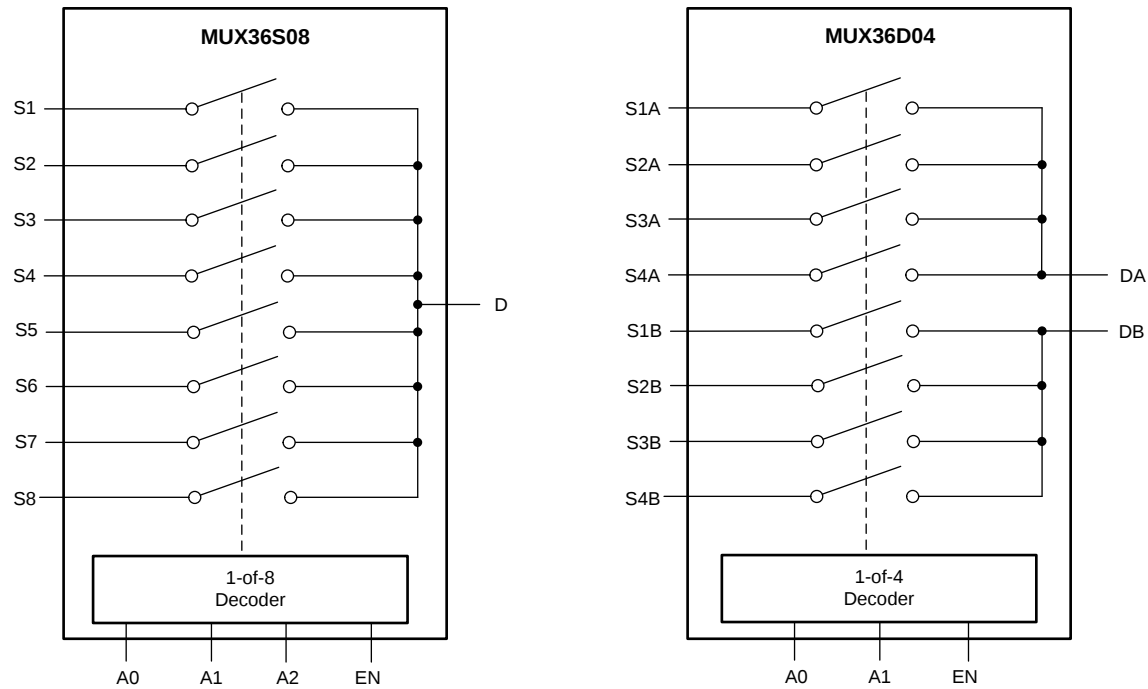
图 37. THD+N Measurement Setup

## 9 Detailed Description

### 9.1 Overview

The MUX36xxx are a family of analog multiplexers. The [Functional Block Diagram](#) section provides a top-level block diagram of both the MUX36S08 and MUX36D04. The MUX36S08 is an 8-channel, single-ended, analog mux. The MUX36D04 is a 4-channel, differential or dual 4:1, single-ended, analog mux. Each channel is turned on or turned off based on the state of the address lines and enable pin.

### 9.2 Functional Block Diagram



## 9.3 Feature Description

### 9.3.1 Ultralow Leakage Current

The MUX36xxx provide extremely low on- and off-leakage currents. The MUX36xxx are capable of switching signals from high source-impedance inputs into a high input-impedance op amp with minimal offset error because of the ultralow leakage currents. 图 38 shows typical leakage currents of the MUX36xxx versus temperature.

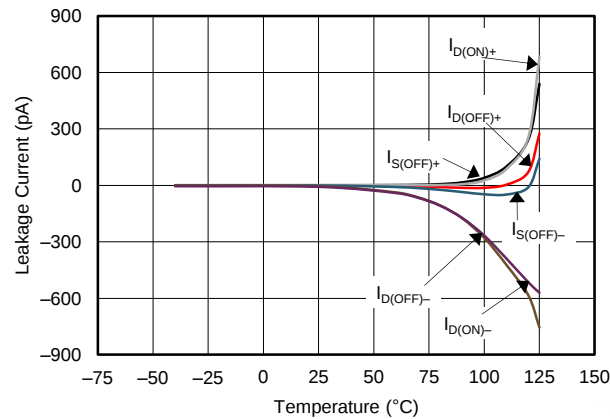


图 38. Leakage Current vs Temperature

### 9.3.2 Ultralow Charge Injection

The MUX36xxx have a simple transmission gate topology, as shown in 图 39. Any mismatch in the stray capacitance associated with the NMOS and PMOS causes an output level change whenever the switch is opened or closed.

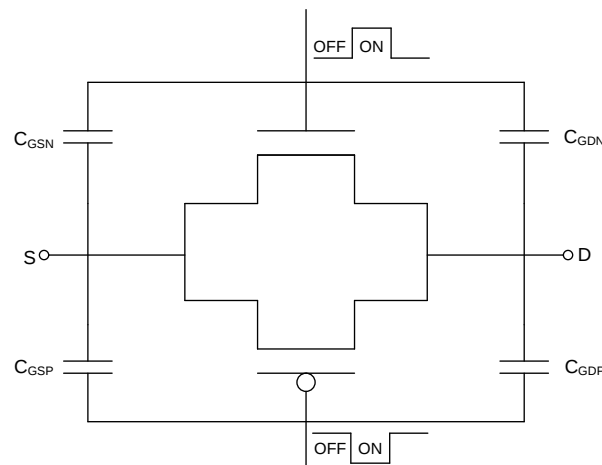


图 39. Transmission Gate Topology

## Feature Description (接下页)

The MUX36xxx have special charge-injection cancellation circuitry that reduces the source-to-drain charge injection to as low as 0.3 pC at  $V_S = 0$  V, and  $\pm 0.6$  pC in the full signal range, as shown in 图 40.

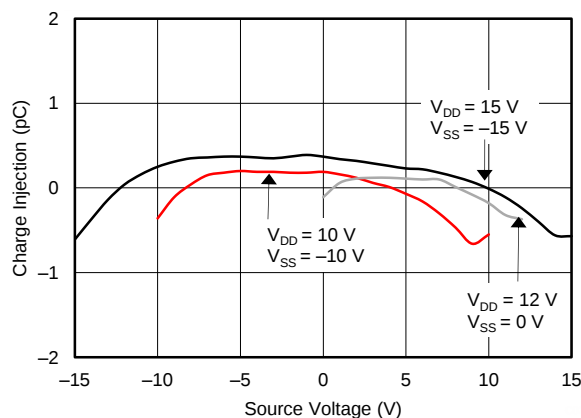


图 40. Source-to-Drain Charge Injection vs Source or Drain Voltage

The drain-to-source charge injection becomes important when the device is used as a demultiplexer (demux), where D becomes the input and Sx becomes the output. 图 41 shows the drain-to-source charge injection across the full signal range.

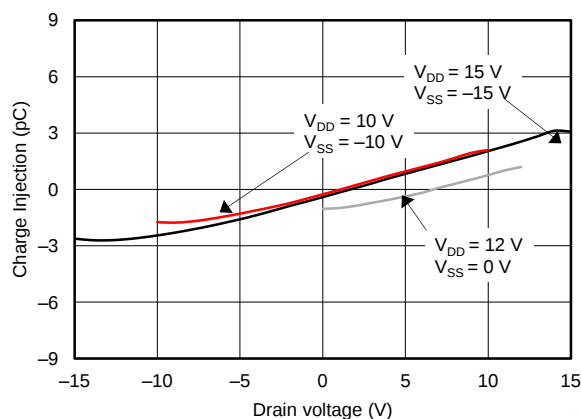


图 41. Drain-to-Source Charge Injection vs Source or Drain Voltage

### 9.3.3 Bidirectional Operation

The MUX36xxx are operable as both a mux and demux. The source (Sx, SxA, SxB) and drain (D, DA, DB) pins of the MUX36xxx are used either as input or output. Each MUX36xxx channel has very similar characteristics in both directions.

## Feature Description (接下页)

### 9.3.4 Rail-to-Rail Operation

The valid analog signal for the MUX36xxx ranges from  $V_{SS}$  to  $V_{DD}$ . The input signal to the MUX36xxx swings from  $V_{SS}$  to  $V_{DD}$  without any significant degradation in performance. The on-resistance of the MUX36xxx varies with input signal, as shown in 图 42

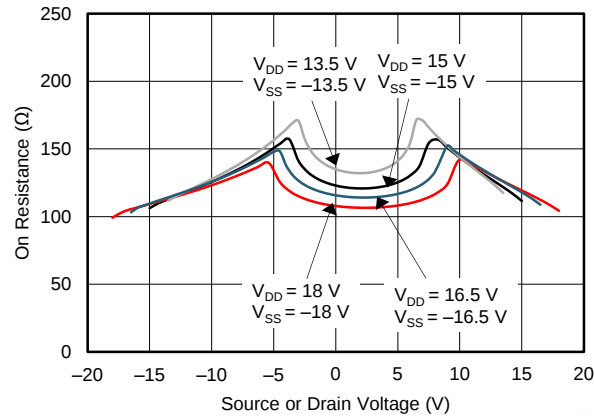


图 42. On-Resistance vs Source or Drain Voltage

## 9.4 Device Functional Modes

When the EN pin of the MUX36xxx is pulled high, one of the switches is closed based on the state of the address lines. When the EN pin is pulled low, all the switches are in an open state irrespective of the state of the address lines. The EN pin can be connected to  $V_{DD}$  (as high as 36 V).

## 10 Application and Implementation

### 注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 10.1 Application Information

The MUX36xxx family offers outstanding input/output leakage currents and ultralow charge injection. These devices operate up to 36 V, and offer true rail-to-rail input and output. The on-capacitance of the MUX36xxx is very low. These features makes the MUX36xxx a family of precision, robust, high-performance analog multiplexer for high-voltage, industrial applications.

### 10.2 Typical Application

图 43 shows a 16-bit, differential, 4-channel, multiplexed, data-acquisition system. This example is typical in industrial applications that require low distortion and a high-voltage differential input. The circuit uses the ADS8864, a 16-bit, 400-kSPS successive-approximation-resistor (SAR) analog-to-digital converter (ADC), along with a precision, high-voltage, signal-conditioning front end, and a 4-channel differential mux. This TI Precision Design details the process for optimizing the precision, high-voltage, front-end drive circuit using the MUX36D04, OPA192 and OPA140 to achieve excellent dynamic performance and linearity with the ADS8864.

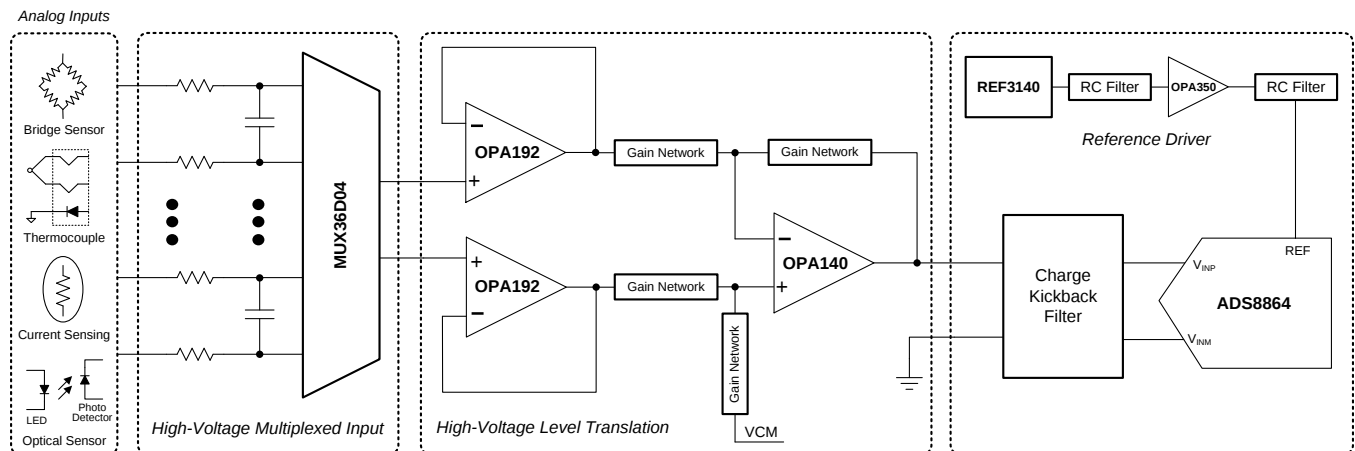


图 43. 16-Bit Precision Multiplexed Data-Acquisition System for High-Voltage Inputs With Lowest Distortion

## Typical Application (接下页)

### 10.2.1 Design Requirements

The primary objective is to design a  $\pm 20$  V, differential, 4-channel, multiplexed, data-acquisition system with lowest distortion using the 16-bit ADS8864 at a throughput of 400 kSPS for a 10-kHz, full-scale, pure, sine-wave input. The design requirements for this block design are:

- System supply voltage:  $\pm 15$  V
- ADC supply voltage: 3.3 V
- ADC sampling rate: 400 kSPS
- ADC reference voltage (REFP): 4.096 V
- System input signal: A high-voltage differential input signal with a peak amplitude of 20 V and frequency ( $f_{IN}$ ) of 10 kHz are applied to each differential input of the mux.

### 10.2.2 Detailed Design Procedure

The purpose of this precision design is to design an optimal, high-voltage, multiplexed, data-acquisition system for highest system linearity and fast settling. The overall system block diagram is illustrated in 图 43. The circuit is a multichannel, data-acquisition signal chain consisting of an input low-pass filter, mux, mux output buffer, attenuating SAR ADC driver, and the reference driver. The architecture allows fast sampling of multiple channels using a single ADC, providing a low-cost solution. This design systematically approaches each analog circuit block to achieve a 16-bit settling for a full-scale input stage voltage and linearity for a 10-kHz sinusoidal input signal at each input channel.



For step-by-step design procedure, circuit schematics, bill of materials, PCB files, simulation results, and test results, refer to [TI Precision Design TIPD151, 16-Bit, 400-kSPS, 4-Channel Multiplexed Data-Acquisition System for High-Voltage Inputs with Lowest Distortion](#).

### 10.2.3 Application Curve

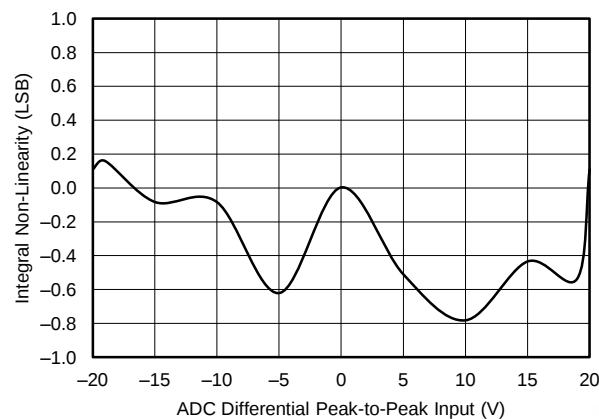


图 44. ADC 16-Bit Linearity Error for the Multiplexed Data-Acquisition Block

## 11 Power Supply Recommendations

The MUX36xxx operates across a wide supply range of  $\pm 5$  V to  $\pm 18$  V (10 V to 36 V in single-supply mode). They also perform well with unsymmetric supplies such as  $V_{DD} = 12$  V and  $V_{SS} = -5$  V. For reliable operation, use a supply decoupling capacitor ranging between 0.1  $\mu$ F to 10  $\mu$ F at both the VDD and VSS pins to ground.

The on-resistance of the MUX36xxx varies with supply voltage, as illustrated in 图 45

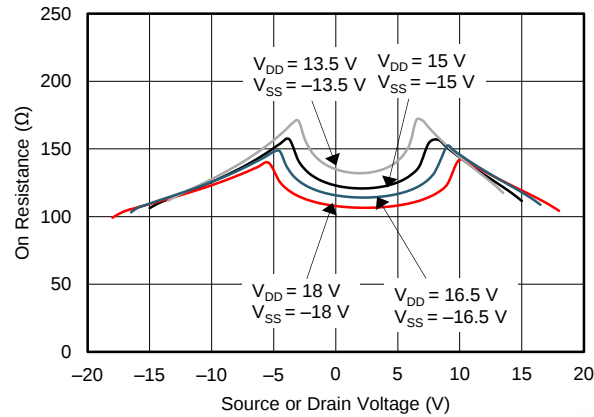


图 45. On-Resistance Variation With Supply and Input Voltage

## 12 Layout

### 12.1 Layout Guidelines

图 46 illustrates an example of a PCB layout with the MUX36S08IPW, and 图 47 illustrates an example of a PCB layout with MUX36D04IPW.

Some key considerations are:

1. Decouple the VDD and VSS pins with a 0.1- $\mu$ F capacitor, placed as close to the pin as possible. Make sure that the capacitor voltage rating is sufficient for the  $V_{DD}$  and  $V_{SS}$  supplies.
2. Keep the input lines as short as possible. In case of the differential signal, make sure the A inputs and B inputs are as symmetric as possible.
3. Use a solid ground plane to help distribute heat and reduce electromagnetic interference (EMI) noise pickup.
4. Do not run sensitive analog traces in parallel with digital traces. Avoid crossing digital and analog traces if possible, and only make perpendicular crossings when necessary.

### 12.2 Layout Example

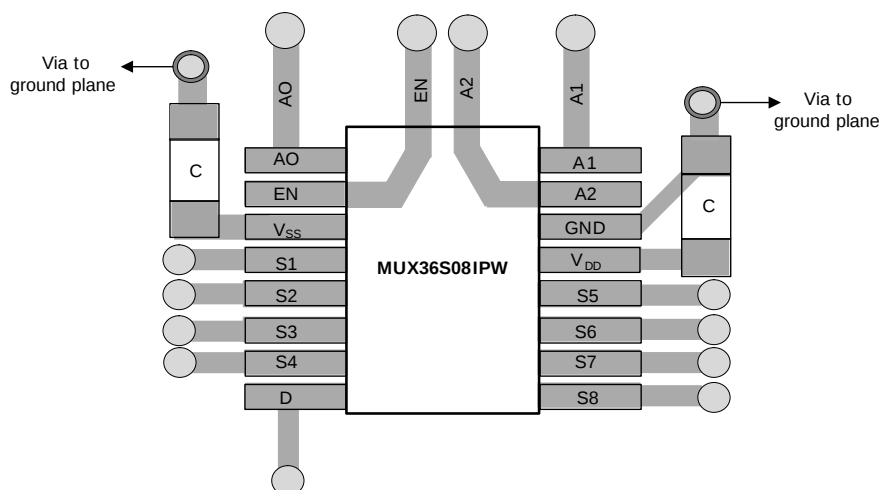


图 46. MUX36S08IPW Layout Example

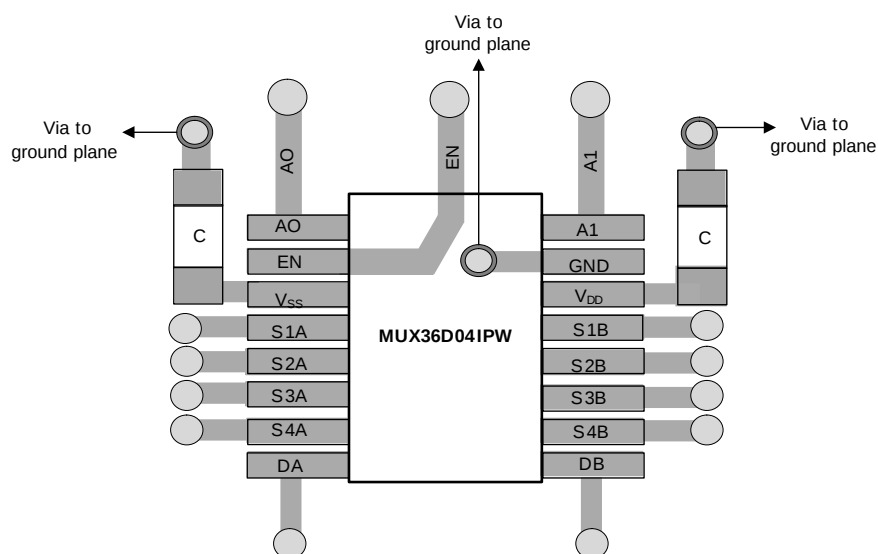


图 47. MUX36D04IPW Layout Example

## 13 器件和文档支持

### 13.1 文档支持

#### 13.1.1 相关文档

- 《支持双极输入范围的 [ADS8664](#) 12 位、500kSPS、4 通道和 8 通道单电源 SAR ADC》(SBAS492)
- 《[OPA140](#) 高精度、低噪声、轨至轨输出、11MHz JFET 运算放大器》(SBOS498)
- 《采用 [e-Trim™](#) 技术的 [OPA192](#) 36V、轨至轨输入/输出、低失调电压、低输入偏置电流运算放大器》(SBOS620)

### 13.2 相关链接

**表 3** 列出了快速访问链接。类别包括技术文档、支持与社区资源、工具与软件，以及申请样片或购买产品的快速链接。

**表 3. 相关链接**

| 器件       | 产品文件夹                | 立即订购                 | 技术文档                 | 工具与软件                | 支持和社区                |
|----------|----------------------|----------------------|----------------------|----------------------|----------------------|
| MUX36S08 | <a href="#">单击此处</a> | <a href="#">单击此处</a> | <a href="#">单击此处</a> | <a href="#">单击此处</a> | <a href="#">单击此处</a> |
| MUX36D04 | <a href="#">单击此处</a> | <a href="#">单击此处</a> | <a href="#">单击此处</a> | <a href="#">单击此处</a> | <a href="#">单击此处</a> |

### 13.3 接收文档更新通知

要接收文档更新通知，请导航至 [TI.com.cn](#) 上的器件产品文件夹。单击右上角的 [通知我](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

### 13.4 社区资源

下列链接提供到 TI 社区资源的连接。链接的内容由各个分销商“按照原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [《使用条款》](#)。

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**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

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All other trademarks are the property of their respective owners.

### 13.6 静电放电警告



ESD 可能会损坏该集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理措施和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

### 13.7 术语表

**SLYZ022** — TI 术语表。

这份术语表列出并解释术语、缩写和定义。

## 14 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请查阅左侧的导航栏。

**PACKAGING INFORMATION**

| Orderable part number         | Status<br>(1) | Material type<br>(2) | Package   Pins  | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-------------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">MUX36D04IPW</a>   | Active        | Production           | TSSOP (PW)   16 | 90   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | MUXD04C             |
| MUX36D04IPW.B                 | Active        | Production           | TSSOP (PW)   16 | 90   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | MUXD04C             |
| <a href="#">MUX36D04IPWR</a>  | Active        | Production           | TSSOP (PW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | MUXD04C             |
| MUX36D04IPWR.B                | Active        | Production           | TSSOP (PW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | MUXD04C             |
| MUX36D04IPWRG4                | Active        | Production           | TSSOP (PW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | MUXD04C             |
| MUX36D04IPWRG4.B              | Active        | Production           | TSSOP (PW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | MUXD04C             |
| <a href="#">MUX36D04IRRJR</a> | Active        | Production           | WQFN (RRJ)   16 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | MUX<br>36D04        |
| MUX36D04IRRJR.B               | Active        | Production           | WQFN (RRJ)   16 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | MUX<br>36D04        |
| <a href="#">MUX36D04IRUMR</a> | Active        | Production           | WQFN (RUM)   16 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | MUX<br>36D04        |
| MUX36D04IRUMR.B               | Active        | Production           | WQFN (RUM)   16 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | MUX<br>36D04        |
| MUX36D04IRUMRG4               | Active        | Production           | WQFN (RUM)   16 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | MUX<br>36D04        |
| MUX36D04IRUMRG4.B             | Active        | Production           | WQFN (RUM)   16 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | MUX<br>36D04        |
| <a href="#">MUX36S08IPW</a>   | Active        | Production           | TSSOP (PW)   16 | 90   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | MUXS08B             |
| MUX36S08IPW.B                 | Active        | Production           | TSSOP (PW)   16 | 90   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | MUXS08B             |
| <a href="#">MUX36S08IPWR</a>  | Active        | Production           | TSSOP (PW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | MUXS08B             |
| MUX36S08IPWR.B                | Active        | Production           | TSSOP (PW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | MUXS08B             |
| MUX36S08IPWRG4                | Active        | Production           | TSSOP (PW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | MUXS08B             |
| MUX36S08IPWRG4.B              | Active        | Production           | TSSOP (PW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | MUXS08B             |
| <a href="#">MUX36S08IRRJR</a> | Active        | Production           | WQFN (RRJ)   16 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | MUX<br>36S08        |
| MUX36S08IRRJR.B               | Active        | Production           | WQFN (RRJ)   16 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | MUX<br>36S08        |
| <a href="#">MUX36S08IRUMR</a> | Active        | Production           | WQFN (RUM)   16 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | MUX<br>36S08        |
| MUX36S08IRUMR.B               | Active        | Production           | WQFN (RUM)   16 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | MUX<br>36S08        |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| MUX36D04IPWR    | TSSOP        | PW              | 16   | 2000 | 330.0              | 12.4               | 6.9     | 5.6     | 1.6     | 8.0     | 12.0   | Q1            |
| MUX36D04IPWRG4  | TSSOP        | PW              | 16   | 2000 | 330.0              | 12.4               | 6.9     | 5.6     | 1.6     | 8.0     | 12.0   | Q1            |
| MUX36D04IRRJR   | WQFN         | RRJ             | 16   | 3000 | 330.0              | 12.4               | 4.25    | 4.25    | 1.15    | 8.0     | 12.0   | Q2            |
| MUX36D04IRUMR   | WQFN         | RUM             | 16   | 3000 | 330.0              | 12.4               | 4.25    | 4.25    | 1.15    | 8.0     | 12.0   | Q2            |
| MUX36D04IRUMRG4 | WQFN         | RUM             | 16   | 3000 | 330.0              | 12.4               | 4.25    | 4.25    | 1.15    | 8.0     | 12.0   | Q2            |
| MUX36S08IPWR    | TSSOP        | PW              | 16   | 2000 | 330.0              | 12.4               | 6.9     | 5.6     | 1.6     | 8.0     | 12.0   | Q1            |
| MUX36S08IPWRG4  | TSSOP        | PW              | 16   | 2000 | 330.0              | 12.4               | 6.9     | 5.6     | 1.6     | 8.0     | 12.0   | Q1            |
| MUX36S08IRRJR   | WQFN         | RRJ             | 16   | 3000 | 330.0              | 12.4               | 4.25    | 4.25    | 1.15    | 8.0     | 12.0   | Q2            |
| MUX36S08IRUMR   | WQFN         | RUM             | 16   | 3000 | 330.0              | 12.4               | 4.25    | 4.25    | 1.15    | 8.0     | 12.0   | Q2            |

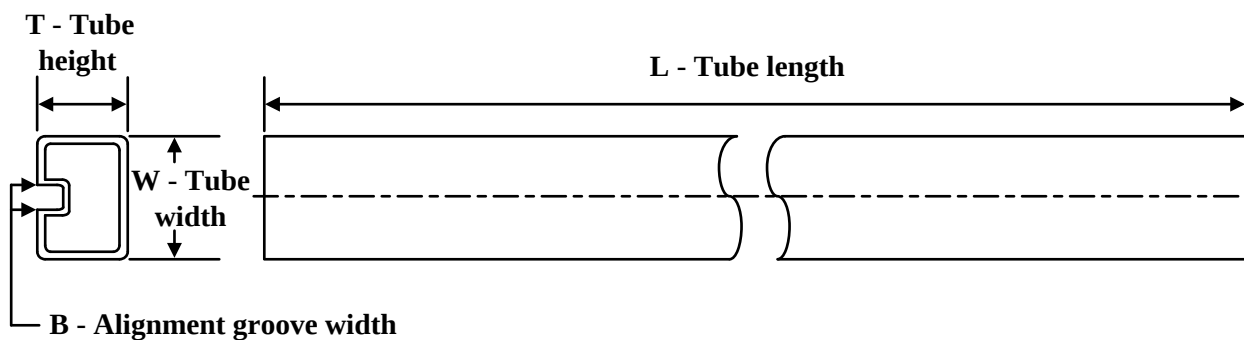
## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

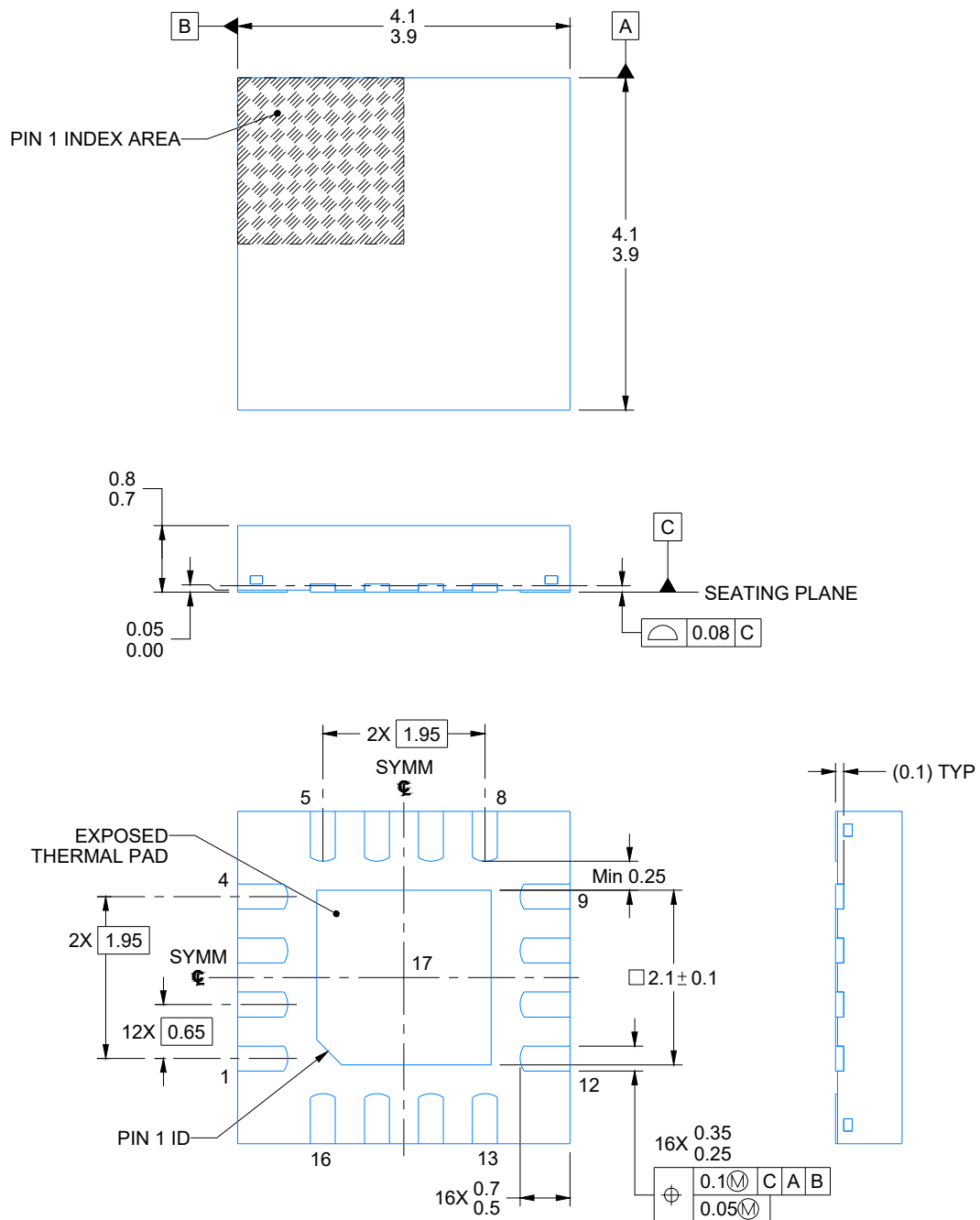
| Device          | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| MUX36D04IPWR    | TSSOP        | PW              | 16   | 2000 | 353.0       | 353.0      | 32.0        |
| MUX36D04IPWRG4  | TSSOP        | PW              | 16   | 2000 | 353.0       | 353.0      | 32.0        |
| MUX36D04IRRJR   | WQFN         | RRJ             | 16   | 3000 | 367.0       | 367.0      | 35.0        |
| MUX36D04IRUMR   | WQFN         | RUM             | 16   | 3000 | 367.0       | 367.0      | 35.0        |
| MUX36D04IRUMRG4 | WQFN         | RUM             | 16   | 3000 | 367.0       | 367.0      | 35.0        |
| MUX36S08IPWR    | TSSOP        | PW              | 16   | 2000 | 353.0       | 353.0      | 32.0        |
| MUX36S08IPWRG4  | TSSOP        | PW              | 16   | 2000 | 353.0       | 353.0      | 32.0        |
| MUX36S08IRRJR   | WQFN         | RRJ             | 16   | 3000 | 367.0       | 367.0      | 35.0        |
| MUX36S08IRUMR   | WQFN         | RUM             | 16   | 3000 | 367.0       | 367.0      | 35.0        |

## TUBE



\*All dimensions are nominal

| Device        | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|---------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| MUX36D04IPW   | PW           | TSSOP        | 16   | 90  | 530    | 10.2   | 3600   | 3.5    |
| MUX36D04IPW.B | PW           | TSSOP        | 16   | 90  | 530    | 10.2   | 3600   | 3.5    |
| MUX36S08IPW   | PW           | TSSOP        | 16   | 90  | 530    | 10.2   | 3600   | 3.5    |
| MUX36S08IPW.B | PW           | TSSOP        | 16   | 90  | 530    | 10.2   | 3600   | 3.5    |



4224485/A 08/2018

## NOTES:

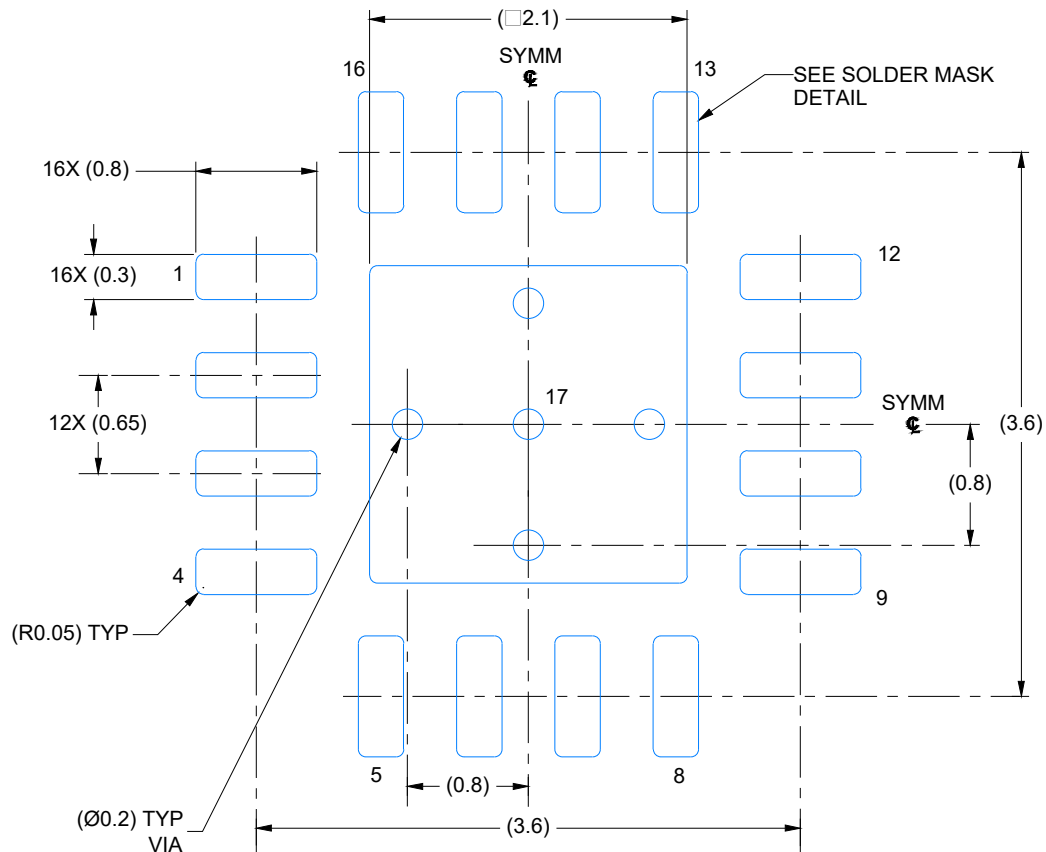
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

# EXAMPLE BOARD LAYOUT

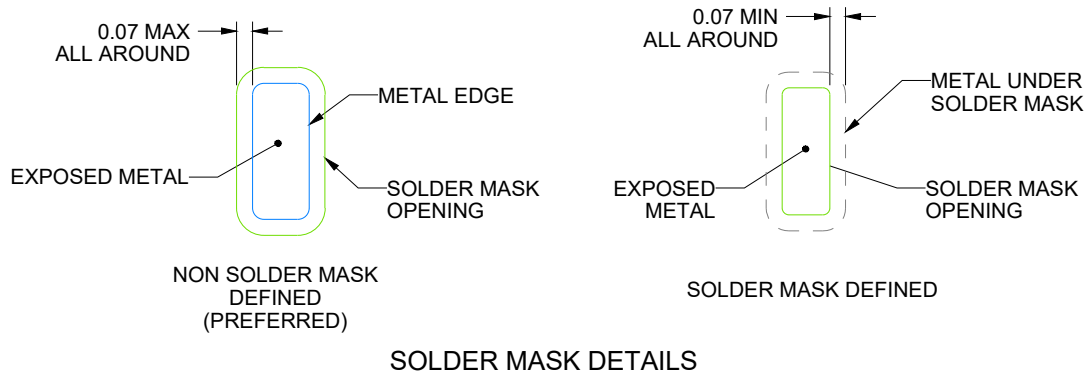
RRJ0016A

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 20X



4224485/A 08/2018

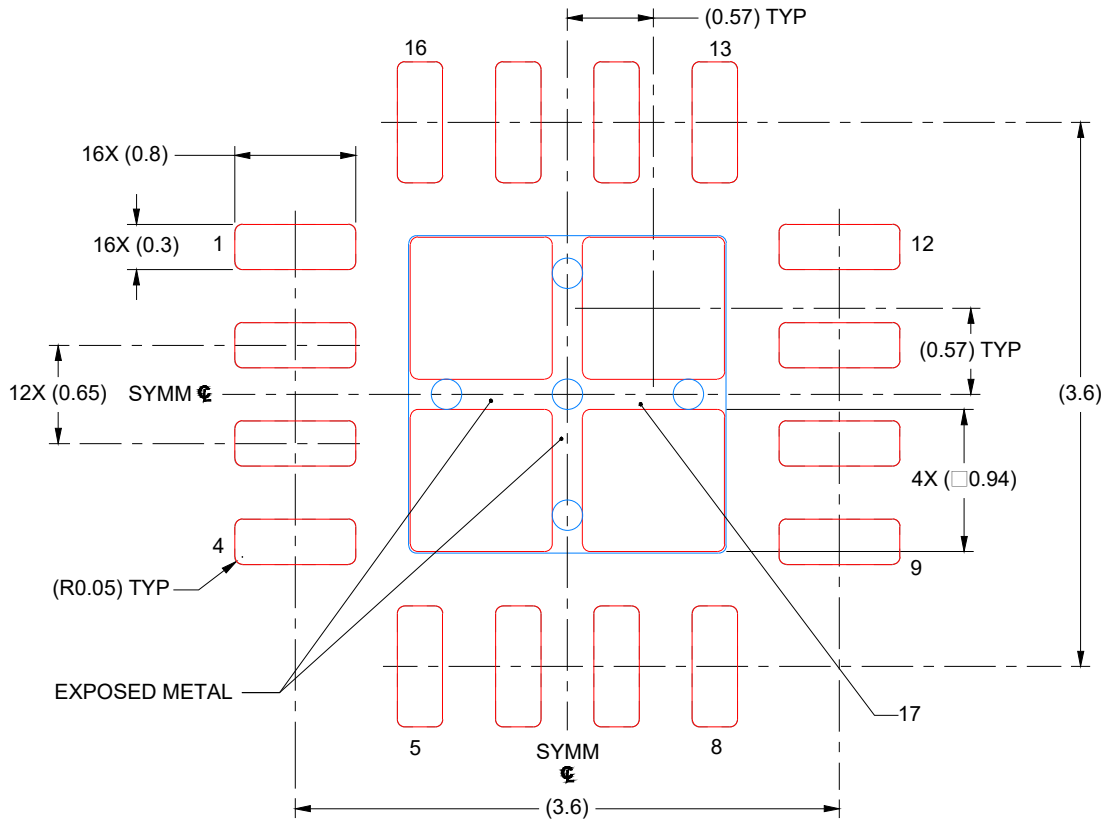
NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slue271](http://www.ti.com/lit/slue271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

**RRJ0016A**

**WQFN - 0.8 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 MM THICK STENCIL  
SCALE: 20X

EXPOSED PAD 17  
80% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE

4224485/A 08/2018

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

## GENERIC PACKAGE VIEW

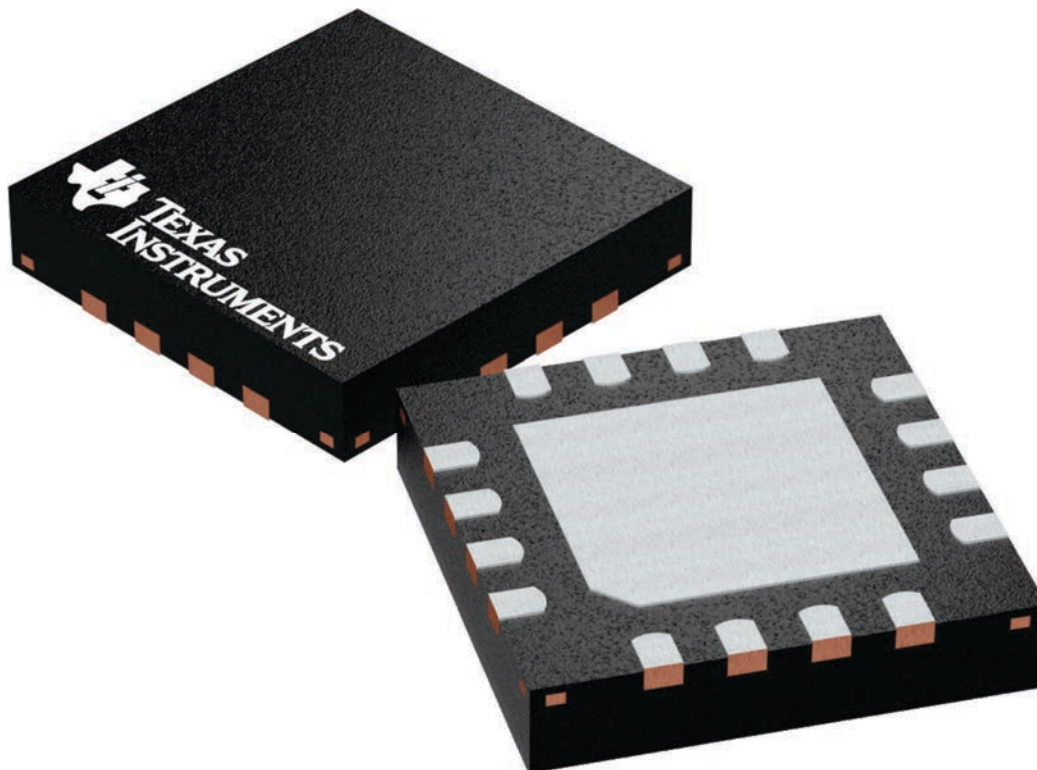
**RUM 16**

**WQFN - 0.8 mm max height**

4 x 4, 0.65 mm pitch

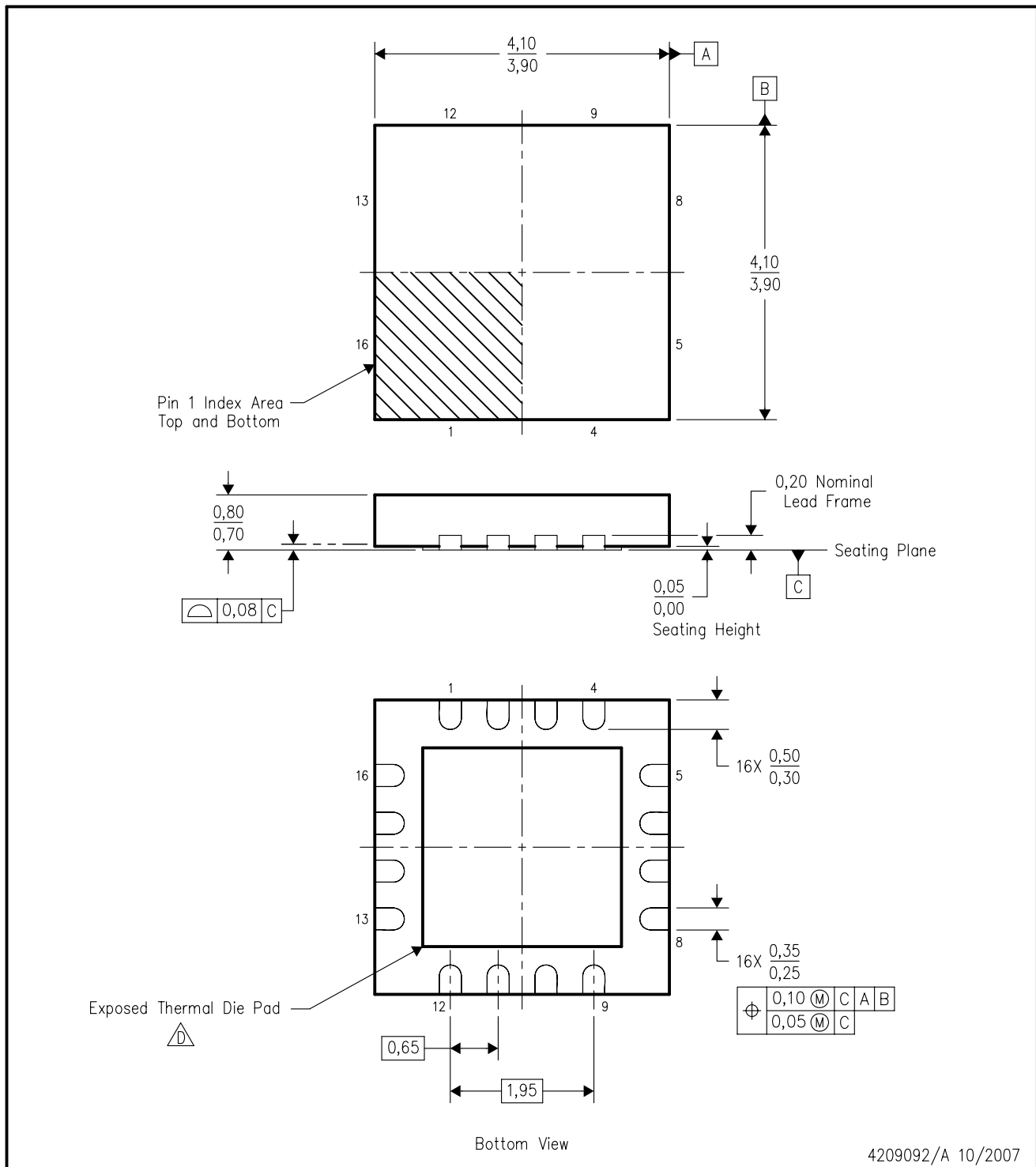
PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



RUM (S-PQFP-N16)

PLASTIC QUAD FLATPACK



4209092/A 10/2007

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - This drawing is subject to change without notice.
  - QFN (Quad Flatpack No-Lead) package configuration.
  - The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
  - Package complies to JEDEC MO-220 variation WGGC-3.

RUM (S-PWQFN-N16)

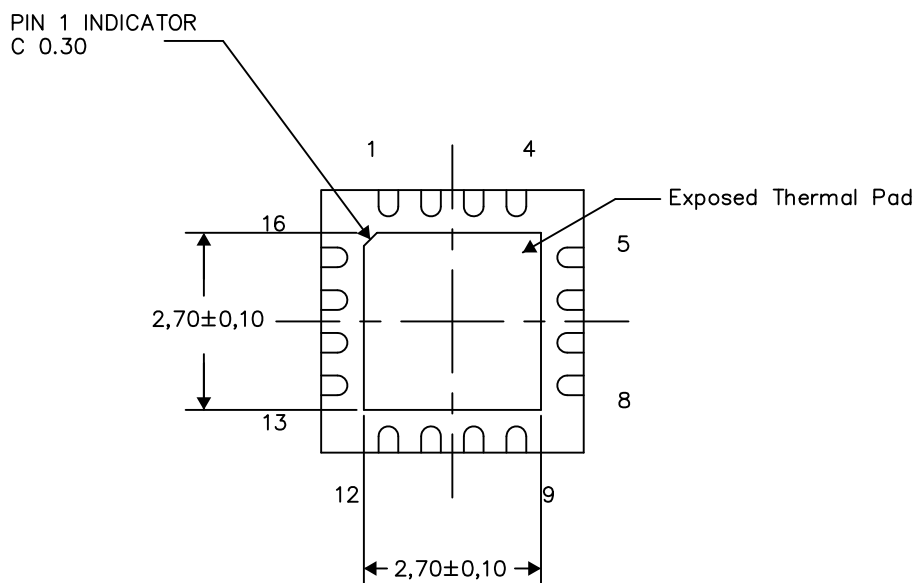
PLASTIC QUAD FLATPACK NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.

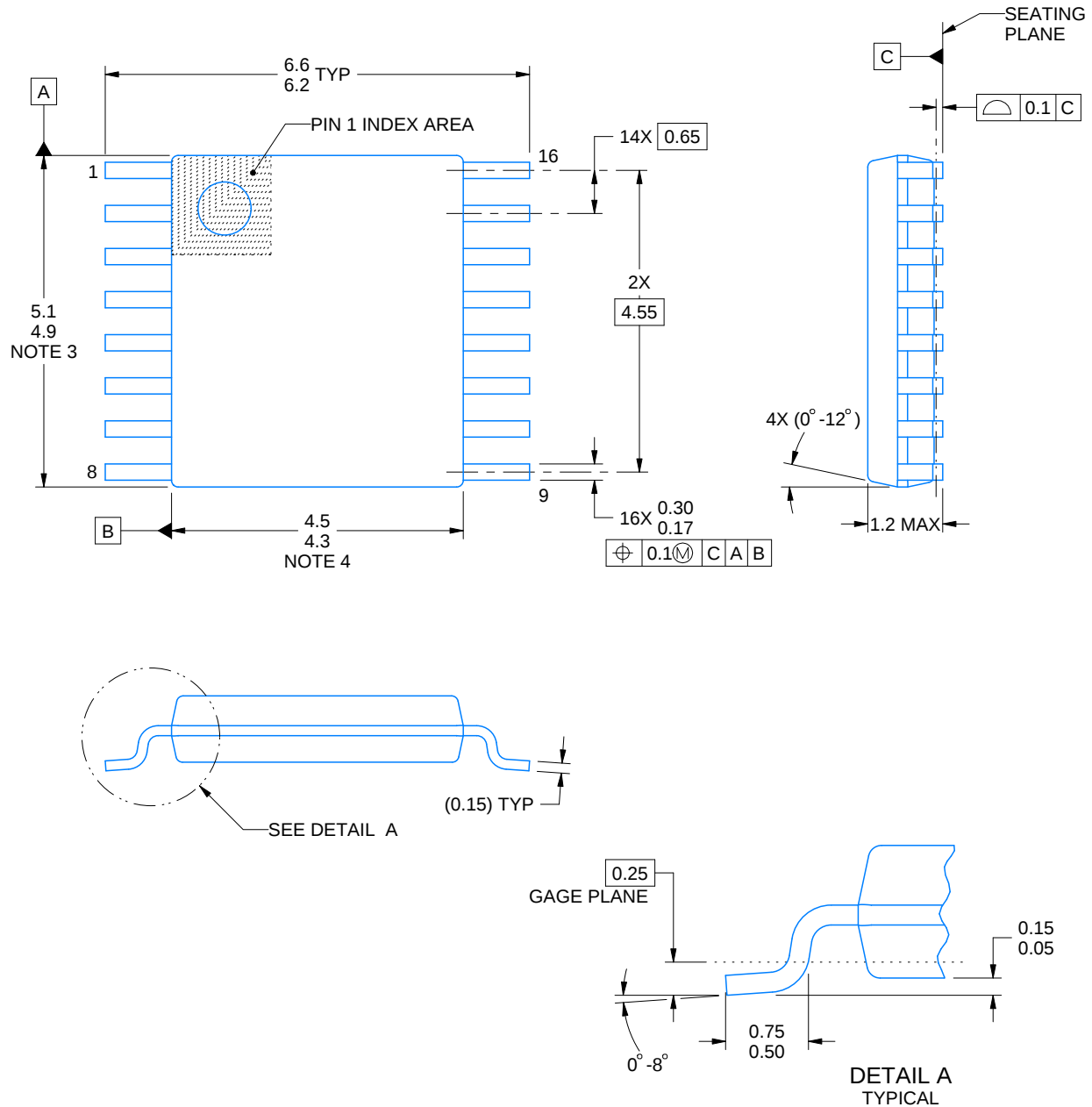
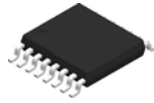


Bottom View

Exposed Thermal Pad Dimensions

4209093-2/F 09/15

NOTES: All linear dimensions are in millimeters



4220204/B 12/2023

## NOTES:

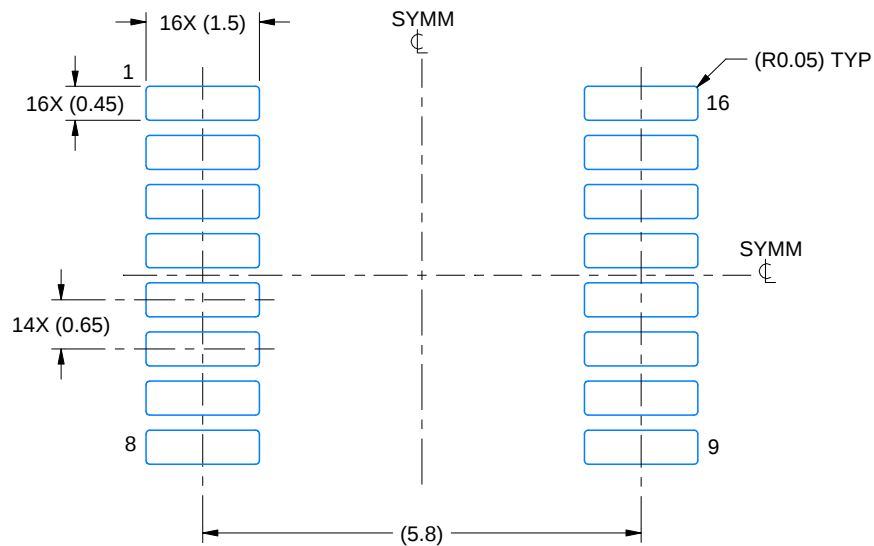
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

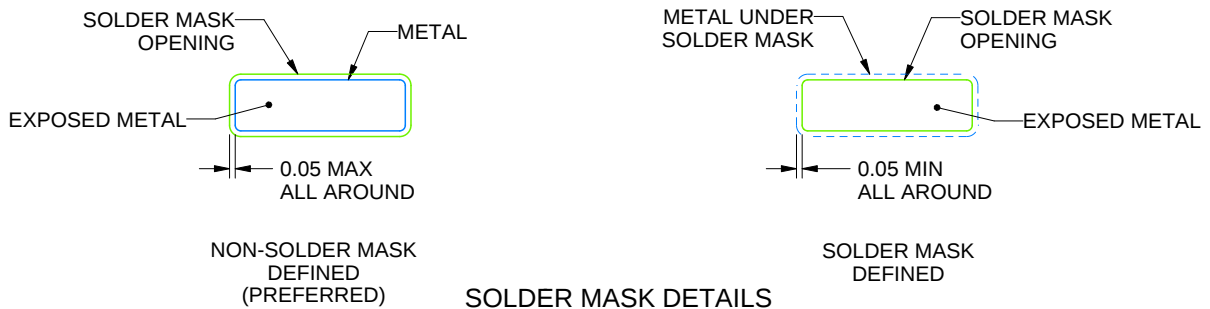
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

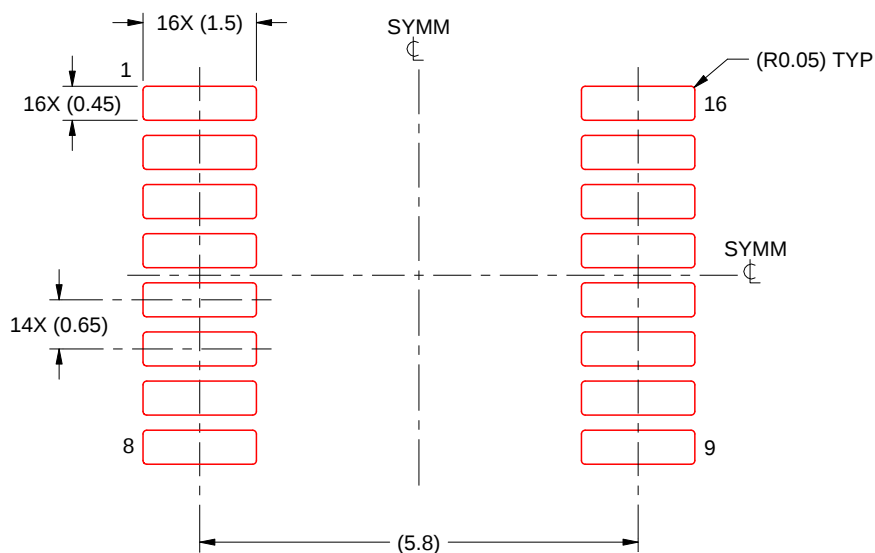
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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